### **Guillaume Saint-Girons (DR2-CNRS, section 8)**

### Production scientifique au 10 juillet 2025

(voir bilan en première page)

### Bilan de la production scientifique

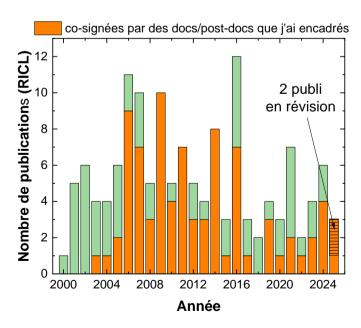
Le tableau ci-dessous donne une idée du volume de ma production scientifique depuis le début de ma carrière et sur la période d'évaluation

	Depuis le début de ma carrière	Sur la période d'évaluation (2017 – 2025)	
Chapitres d'ouvrage et monographies	7	1	
Brevets	9	3	
Conférences invitées	49 dont -28 internationales (13 perso) -21 nationales (13 perso)	14 dont - 5 internationales (2 perso) - 9 nationales (5 perso)	
Séminaires invités	12 (5 internationaux)	2 (1 international)	
Revues internationales à comité de lecture	139 (+ 2 en révision)	32 (+ 2 en révision)	
<b>Conférences internationales</b>	157	39	
Conférences nationales	130	39	

h-factor: **34** (Google Scholar, 10 juillet 2025)

Dans la liste de publications qui suit, les titres des publications correspondant à la pédiode d'évaluation sont en rouge. Les noms des doctorants que j'ai encadrés sont indiqués en orange. 85 des 141 publications dans des revues internationales à comité de lecture dont je suis auteur sont co-signées par des doctorants que j'ai encadrés (soit environ 60%).

La figure ci-dessous, dans laquelle les barres orange donnent la fraction de mes publications co-signées par des doctorants que j'ai encadrés, illustre l'évolution de ma production scientifique.



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#### **Brevets**

#### 1. InGaAs/GaAs lasers on silicon produced by LEPECVD and MOCVD

EPISPEED AG, H. von Känel, I. Sagnes, G. Saint-Girons, S. Bouchoule Pub. N° WO/2005/025019, app. N° PCT/EP2004/009873, 17.03.2005

#### 2. High-k heterostructure

C. Merckling, M. El-Kazzi, G. Saint-Girons and G. Hollinger Pub. N° WO/2009/027765, app. N° PCT/IB2007/003415, 28.08.2007

#### 3. Epitaxial solid state semiconducting hetero-structures and method for making same

G. Saint-Girons, P. Regreny, G. Hollinger, G. Patriarche, L. Largeau Pub. N° WO/2009/047448, app. N° PCT/FR2008/051669, 17.09.2008

### 4. Système de contrôle de dépôt de couches minces comportant une source de lumière continue et un spectromètre

G. Saint-Girons, R. Rousseau, C. Botella, J. Morville Enregistrement INPI FR2308685, 11.08.2023 <a href="https://hal.science/hal-04243462">https://hal.science/hal-04243462</a> WO2025036783A1/ FR3152058A1

### 5. Système de contrôle de dépôt de couches minces comportant une source de lumière continue et une cavité optique

G. Saint-Girons, R. Rousseau, C. Botella, J. Morville Enregistrement INPI FR2308684, 11.08.2023 https://hal.science/hal-04243465 WO2025036782A1/ FR3152057A1

#### 6. Système de contrôle de dépôt de couches minces comportant une cavité optique

G. Saint-Girons, R. Rousseau, C. Botella, J. Morville Enregistrement INPI FR2308666, 11.08.2023 <a href="https://hal.science/hal-04243469">https://hal.science/hal-04243469</a> WO2025036781A1/FR3152056A1

#### **Monographies**

#### Thèse de doctorat

Epitaxie en phase vapeur aux organométalliques et caractérisations structurales et optiques de boîtes quantiques d'In(Ga)As pour l'émission autour de 1,3 µm sur substrat de GaAs G. Saint-Girons, Université Paris VI-Jussieu, Marcoussis, 3 avril 2002.

Jury : Y. Guldner, J. Massies, P. Boucaud, B. Deveaud-Pledran, E. Rosencher, B. Etienne, I. Sagnes

Thèse publiée aux éditions des Presses Académiques Francophones, ISBN 3838189752

#### Habilitation à diriger des recherches

#### Epitaxie des systèmes hétérogènes

G. Saint-Girons, Université Claude-Bernard/Lyon 1, Ecole Centrale de Lyon, 5 juin 2009 Jury : J. Massies, P. Müller, F. Glas, J. Fompeyrine, M-N. Semeria, J-L. Barrat, G. Hollinger, G. Patriarche

#### Chapitres d'ouvrages

### 1. « Vers l'intégration d'hétérostructures et de nanostructures III-V et Ge sur silicium pour la microélectronique et l'optoélectronique »

G. Saint-Girons, M. Gendry, H. dumont, P. Regreny, J. Cheng, K. Naji, B. Vilquin, G. Niu, G. Grenet, Y. Robach, G. Hollinger, G. Patriarche, L. Largeau, C. Priester, I. Devos pp. 179-182 in La micro-nanoélectronique, enjeux et mutations, CNRS editions, 2009. ISBN 978-2-271-06829-3

2. « Epitaxie d'oxydes fonctionnels sur silicium pour la microélectronique avancée » B. Vilquin, P. Lecoeur, G. Niu, S. Autier-Laurent, G. Saint-Girons, V. Pillard, Y. Robach, G. Hollinger

in La micro-nanoélectronique, enjeux et mutations, CNRS editions, 2009. ISBN 978-2-271-06829-3

3. «Crystalline oxides, strain and epitaxial growth: epitaxy of highly dissimilar systems »

G. Saint-Girons

in "Mechanics of Nano-Objects", Presses des Mines 2011. https://www.pressesdesmines.com/produit/mechanics-of-nano-objects/

### 4. "Development of Epitaxial Oxide Ceramics Nanomaterials Based on Chemical Strategies on Semiconductor Platforms"

A Carretero-Genevrier, R Bachelet, G Saint-Girons, R Moalla, JM Vila-Fungueiriño, B Rivas-Murias, F Rivadulla, J Rodriguez-Carvajal, A Gomez, J Gazquez, M Gich, N Mestres in "Advanced Ceramic, Materials", Wiley 2016.

https://onlinelibrary.wiley.com/doi/book/10.1002/9781119242598

#### 5. « Epitaxial systems combining oxides and semiconductors »

G. Niu, G. Saint-Girons and B. Vilguin

Chap.18 (pp. 451-475) in Molecular Beam Epitaxy: from Research to Mass Production, Elsevier 2012, ISBN 978-0-12-387839-7

Second Ed. Chap.17 (pp.377-402), 2018

https://doi.org/10.1016/B978-0-12-812136-8.00018-9

#### Publications dans des revues internationales à comité de lecture

### 1. 1,3µm electroluminescence of LP-MOVPE grown InAs/GaAs quantum dots, and influence of the re-growth temperature on the spectral response

G. Saint-Girons, A. Mereuta, J.M. Gérard, A. Ramdane, I. Sagnes Mat. Sci. Engin. B **78**, 145, (2000).

https://doi.org/10.1016/S0921-5107(00)00542-0

### 2. Bimodal distribution of Indium composition in arrays of Low-Pressure Metal-Organic Vapour-Phase Epitaxy grown InGaAs/GaAs quantum dots

G. Saint-Girons, G. Patriarche, L. Largeau, J. Coelho, A. Mereuta, J.M. Moison, J.M. Gérard, I. Sagnes

Appl. Phys. Lett. 79, 2157, (2001).

https://doi.org/10.1063/1.1406553

#### 3. Investigations on GaAsSbN/GaAs quantum wells for 1.3-1.55 µm emission

J.C. Harmand, G. Ungaro, J. Ramos, E.V.K. Rao, G. Saint-Girons, R. Teissier, G. Le Roux, L. Largeau, G. Patriarche

J. Cryst. Growth 227, 553, (2001).

https://doi.org/10.1016/S0022-0248(01)00765-5

#### 4. MOCVD InP/AlGaInAs Distributed Bragg Reflector for 1.55 µm VCSEL

I. Sagnes, G. Le Roux, C. Mériadec, A. Mereuta, G. Saint-Girons, M. Bensoussan Electron. Lett. **37**, 500, (2001).

10.1049/el:20010329

#### 5. (InGa)(NAs)/GaAs structures emitting in 1-1.6 µm wavelength range

A. Mereuta, G. Saint-Girons, S. Bouchoule, I. Sagnes, F. Alexandre, G. Le Roux, J. Decobert and A. Ougazzaden

Opt. Mat. 17, 185, (2001).

https://doi.org/10.1016/S0925-3467(01)00079-9

### 6. Influence of the thermal treatment on the optical and structural properties of 1.3 µm emitting LP-MOVPE grown InAs/GaAs quantum dots

G. Saint-Girons, A. Mereuta, G. Patriarche, J.M. Gérard and I. Sagnes Opt. Mat. 17, 263, (2001).

https://doi.org/10.1016/S0925-3467(01)00089-1

### 7. Metal-Organic Vapour-Phase Epitaxy of defect-free InGaAs/GaAs quantum dots emitting around 1.3 µm

G. Saint-Girons, G. Patriarche, L. Largeau, J. Coelho, A. Mereuta, J.M. Gérard, I. Sagnes J. Cryst. Growth **235**, 89, (2002).

https://doi.org/10.1016/S0022-0248(01)01817-6

#### 8. Origin of the bimodal distribution of Low-Pressure Metal-Organic Chemical-Vapor-Epitaxy grown InGaAs/GaAs quantum dots

G. Saint-Girons, G. Patriarche, A. Mereuta, I. Sagnes

J. Appl. Phys. **91**, 3859, (2002).

### 9. Photoluminescence quenching of a Low-Pressure Metal-Organic Vapor-Phase-Epitaxy grown quantum dots array with bimodal inhomogeneous broadening.

G. Saint-Girons, I. Sagnes

J. Appl. Phys. 91, 10115, (2002).

https://doi.org/10.1063/1.1481968

### 10. <500-fs soliton pulse in a passively mode – locked broadband surface-emitting laser with 100-mW average power

A. Garnache, S. Hoogland, A.C. Tropper, I. Sagnes, G. Saint-Girons, J.S. Roberts Appl. Phys. Lett. **80**, 3892, (2002).

https://doi.org/10.1063/1.1482143

#### 11. Near-infrared waveguide photodetector with Ge/Si self-assembled quantum dots

M. Elkurdi, P. Boucaud, S. Sauvage, O. Kermarrec, Y. Campidelli, D. Bensahel, G. Saint-Girons, I. Sagnes

Appl. Phys. Lett. 80, 509, (2002).

https://doi.org/10.1063/1.1435063

#### 12. Silicon-on-insulator waveguide photodetector with Ge/Si self-assembled islands

M. El kurdi, P. Boucaud, S. Sauvage, G. Fishman, O. Kermarrec, Y. Campidelli, D. Bensahel, G. Saint-Girons, I. Sagnes, and G. Patriarche

J. Appl. Phys. **92**, 1858, (2002).

https://doi.org/10.1063/1.1493656

### 13. CW operation of 1.5 µm optically-pumped external-cavity VCSEL monolithically grown by MOCVD

C. Symonds, I. Sagnes, A. Garnache, S. Hoogland, G. Saint-Girons, A. Mereuta, A.C. Tropper and J.L. Oudar

Applied Optics 42, 6678, (2003).

10.1364/AO.42.006678

### 14. Room Temperature laser operation of strained InGaAs/GaAs QW structure monolithically grown by MOVCD on LE-PECVD Ge/Si virtual substrate

Y. Chriqui, G. Saint-Girons, S. Bouchoule, G. Isella, H. von Kaenel, I. Sagnes Electron. Lett **39**, 1658, (2003).

10.1049/el:20030926

### 15. Silicon-on-insulator and SiGe waveguide photodetectors with Ge/Si self-assembled islands

M. El kurdi, P. Boucaud, S. Sauvage, G. Fishman, O. Kermarrec, Y. Campidelli, D. Bensahel, G. Saint-Girons, G. Patriarche and I. Sagnes.

Physica E **16**, 523, (2003).

https://doi.org/10.1016/S1386-9477(02)00633-1

### 16. Electromodulation of the interband and intraband absorption of Ge/Si self assembled islands

M. Elkurdi, P. Boucaud, S. Sauvage, G. Fishman, O. Kermarrec, Y. Campidelli, D. Bensahel, G. Saint-Girons, G. Patriarche and I. Sagnes.

Physica E **16**, 450, (2003).

https://doi.org/10.1016/S1386-9477(02)00630-6

### 17. Photoluminescence probing of non-radiative channels in hydrogenated In(Ga)As/GaAs quantum dots

G. Saint-Girons, A. Lemaître, V. Navarro-Paredes, G. Patriarche, E.V.K. Rao, I. Sagnes and B. Theys.

J. Cryst. Growth **264**, 334, (2004).

https://doi.org/10.1016/j.jcrysgro.2004.01.017

# 18. Direct growth of GaAs based structures on exactly (001)-oriented Ge/Si virtual substrates : reduction of the structural defect density and observation of electroluminescence at room temperature under CW electrical injection.

Y. Chriqui, L. Largeau, G. Patriarche, G. Saint-Girons, S. Bouchoule, I. Sagnes, D. Bensahel, Y. Campidelli and O. Kermarrec

J. Cryst. Growth **265**, 53, (2004).

https://doi.org/10.1016/j.jcrysgro.2004.01.038

### 19. Long-range ordering of III-V semiconductor nanostructures by shallowly buried dislocation networks

J. Coelho, G.Patriarche, F. Glas, G. Saint-Girons, and I. Sagnes

J. Phys: Condens. Matter 16, 7941, (2004).

https://doi.org/10.1088/0953-8984/16/45/016

### 20. Buried dislocation networks designed to organize the growth of III-V semiconductor nanostructures

J. Coelho, G. Patriarche, F. Glas, G. Saint-Girons, I. Sagnes and L. Largeau Phys. Rev. B **70**, 155329, (2004).

https://doi.org/10.1103/PhysRevB.70.155329

## 21. Long-wavelength room-temperature operation of a strained InGaAs/GaAs quantum well structure monolithically grown by MOCVD on a LE-PECVD graded misoriented Ge/Si virtual substrate

Y. Chriqui, G. Saint-Girons, G. Isella, H. Von Kaenel, S. Bouchoule, I. Sagnes Opt. Mat. 27, 846, (2005).

https://doi.org/10.1016/j.optmat.2004.08.022

#### 22. Stess-engineered orderings of self-assembled III-V semiconductor nanostructures

J. Coelho, G. Patriarche, F. Glas, I. Sagnes and G. Saint-Girons

Phys. Stat. Sol.c 2, 1245, (2005).

https://doi.org/10.1002/pssc.200460413

#### 23. Electroabsorption spectroscopy of Ge/Si self-assembled islands

M. El kurdi, P. Boucaud, S. Sauvage, G. Fishman, O. Kermarrec, Y. Campidelli, D. Bensahel, G. Saint-Girons, I. Sagnes, and G. Patriarche

J. Appl. Phys. 97, 083525, (2005).

https://doi.org/10.1063/1.1874296

#### 24. Dislocation networks adapted to order the growth of III-V semiconductor nanostructures

J. Coelho, G. Patriarche, F. Glas, I. Sagnes and G. Saint-Girons

Phys. Stat. Sol.c 2, 1933, (2005).

https://doi.org/10.1002/pssc.200460528

#### 25. Carrier dynamics in GaInAs/InP near-surface quantum wells

C. Symonds, J. Mangeney, G. Saint-Girons and I. Sagnes

Appl. Phys. Lett. 87, 012107, (2005).

https://doi.org/10.1063/1.1993763

### 26. InAs/InP(001) quantum dots emitting at 1.55 µm grown by Low-Pressure Metalorganic Vapor-Phase Epitaxy

A. Michon, G. Saint-Girons, G. Beaudoin, I. Sagnes, L. Largeau and G. Patriarche Appl. Phys. Lett. **87**, 253114, (2005).

https://doi.org/10.1063/1.2150271

#### 27. Buried dislocation networks for the controlled growth of III-V semiconductors

F. Glas, J. Coelho, G. Patriarche, G. Saint-Girons

J. Cryst. Growth 275, e1647, (2005).

https://doi.org/10.1016/j.jcrysgro.2004.11.219

# 28. Indium incorporation in In-rich InGaAs/GaAs layers grown by Low-Pressure Metalorganic Vapor Phase Epitaxy and its influence on the growth of self-assembled quantum dots.

G. Saint-Girons, I. Sagnes and G. Patriarche.

Phys. Rev. B 73, 045308, (2006).

https://doi.org/10.1103/PhysRevB.73.045308

### 29. Microphotoluminescence of exciton and biexciton around 1.5 $\mu$ m from a single InAs/InP(001) quantum dot.

G. Saint-Girons, N. Chauvin, A. Michon, G. Patriarche, G. Beaudoin, G. Brémond, C. Bru-Chevallier and I. Sagnes.

Appl. Phys. Lett. 88, 133101, (2006).

https://doi.org/10.1063/1.2185008

### 30. Nanoepitaxy of InAs/InP quantum dots by metalorganic vapor phase epitaxy for 1.55 $\mu$ m emittors

J.M. Benoît, L. Le Gratiet, G. Beaudoin, A. Michon, G. Saint-Girons, R. Kuszelewicz and I. Sagnes

Appl. Phys. Lett. 88, 041113, (2006).

https://doi.org/10.1063/1.2167804

### 31. Thermodynamical analysis of the dispersion in size and shape of InAs/InP(001) quantum dots.

A. Michon, I. Sagnes, G. Patriarche, G. Beaudoin, M.N. Mérat-Combes and G. Saint-Girons. Phys. Rev. B 73, 165321, (2006).

https://doi.org/10.1103/PhysRevB.73.165321

### 32. Effect of cap-layer growth rate on morphology and luminescence of InAs/InP(001) quantum dots grown by Metalorganic Vapor-Phase Epitaxy

A. Michon, I. Sagnes, G. Patriarche, G. Beaudoin, M.N. Mérat-Combes and G. Saint-Girons.

J. Appl. Phys. 100, 033508, (2006).

### 33. Thermodynamic description of the competition between quantum dashes in the InAs/InP(001) system

G. Saint-Girons, A. Michon, I. Sagnes, G. Beaudoin and G. Patriarche Phys. Rev. B **74**, 245305, (2006).

https://doi.org/10.1103/PhysRevB.74.245305

### 34. Initial stage of the overgrowth of InP on InAs/InP(001) quantum dots: formation of InP terraces driven by preferential nucleation on quantum dot edges.

G. Saint-Girons, G. Patriarche, A. Michon, G. Beaudoin, I. Sagnes, K. Smaali and M. Troyon Appl. Phys. Lett. **89**, 031923, (2006).

https://doi.org/10.1063/1.2233554

### 35. Imaging the electric properties of InAs/InP(001) quantum dots capped with a thin InP layer by conductive atomic force microscopy. Evidence of memory effect

K. Smaali, M. Troyon, A. El Hdiy, M. Molinari, G. Saint-Girons and G. Patriarche Appl. Phys. Lett. **89**, 112115, (2006).

https://doi.org/10.1063/1.2349288

### 36. Structural properties of epitaxial SrTiO<sub>3</sub> thin films grown by molecular beam epitaxy on Si(001)

G. Delhaye, C. Merckling, M. El-Kazzi, G. Saint-Girons, M. Gendry, Y. Robach, G. Hollinger, L. Largeau and G. Patriarche

J. Appl. Phys. 100, 124109, (2006).

https://doi.org/10.1063/1.2407273

### 37. Pseudomorphic MBE growth of $\gamma$ -Al<sub>2</sub>O<sub>3</sub>(001) on Si(001) and evidence for spontaneous lattice reorientation during epitaxy

C. Merckling, M. El-Kazzi, G. Delhaye, G. Saint-Girons, G. Hollinger L. Largeau and G. Patriarche

Appl. Phys. Lett. 89, 232907, (2006).

https://doi.org/10.1063/1.2403902

### 38. InAs/InP(001) quantum dots and quantum sticks grown by MOVPE: shape, anisotropy and formation process

A. Michon, G. Patriarche, I. Sagnes, G. Beaudoin, and G. Saint-Girons

Phys. Stat. Sol. c 3, 3928, (2006).

https://doi.org/10.1002/pssc.200671539

#### 39. InAs nanocrystals on SiO<sub>2</sub>/Si by molecular beam epitaxy for memory applications

M. Hocevar, P. Regreny, A. Descamps, D. Albertini, G. Saint-Girons, A. Souifi, M. Gendry, and G. Patriarche

Appl. Phys. Lett. 91, 133114 (2007).

https://doi.org/10.1063/1.2793694

### 40. Density of InAs/InP(001) quantum dots grown by metal-organic vapor phase epitaxy: Independent effects of InAs and cap-layer growth rates

A. Michon, G. Patriarche, G. Beaudoin, G. Saint-Girons, N. Gogneau, and I. Sagnes Appl. Phys. Lett. **91**, 102107 (2007).

### 41. Growth of crystalline $\gamma$ -Al<sub>2</sub>O<sub>3</sub> on Si by molecular beam epitaxy: Influence of the substrate orientation

C. Merckling, M. El-Kazzi, G. Saint-Girons, G. Hollinger, L. Largeau, G. Patriarche, V. Favre-Nicolin, and O. Marty

J. Appl. Phys. 102, 024101 (2007).

https://doi.org/10.1063/1.2753684

### 42. Development of robust interfaces based on crystalline $\gamma$ -Al<sub>2</sub>O<sub>3</sub>(001) for subsequent deposition of amorphous high- $\kappa$ oxides

C. Merckling, M. El-Kazzi, L. Becerra, L. Largeau, G. Patriarche, G. Saint-Girons and G. Hollinger

Microelec. Eng. 84, 2243 (2007).

https://doi.org/10.1016/j.mee.2007.04.053

### 43. Strain relaxation and critical thickness for epitaxial LaAlO<sub>3</sub> thin films grown on SrTiO<sub>3</sub>(001) substrates by molecular beam epitaxy

C. Merckling, M. El-Kazzi, G. Delhaye, V. Favre-Nicolin, Y. Robach, M. Gendry, G. Grenet, G. Saint-Girons and G. Hollinger

J. Cryst. Growth 306, 47, (2007).

https://doi.org/10.1016/j.jcrysgro.2007.04.048

# 44. Thermodynamic analysis of the shape, anisotropy and formation process of InAs/InP(001) quantum dots and quantum sticks grown by metalorganic vapor phase epitaxy G. Saint-Girons, A. Michon, I. Sagnes, G. Beaudoin and G. Patriarche

Surf. Sci. 601, 2765 (2007).

10.1016/j.susc.2006.12.040

https://doi.org/10.1016/j.susc.2006.12.040

#### 45. Epitaxial growth of LaAlO<sub>3</sub> on Si(001) using interface engineering

C. Merckling, G. Delhaye, M. El-Kazzi, S. Gaillard, Y. Rozier, L. Rapenne, B. Chenevier, O. Marty, G. Saint-Girons, M. Gendry, Y. Robach and G. Hollinger

Microelectronics Reliability 47, 540 (2007).

https://doi.org/10.1016/j.microrel.2007.01.036

### 46. Monolithic integration of InP based heterostructures on silicon using crystalline Gd<sub>2</sub>O<sub>3</sub> buffers

G. Saint-Girons, G. P. Regreny L. Largeau L, G. Patriarche, G. Hollinger.

Appl. Phys. Lett. 91, 241912 (2007).

https://doi.org/10.1063/1.2824466

### 47. Ultralow equivalent oxide thickness obtained for thin amorphous LaAlO3 layers grown on Si(001)

L. Becerra, C. Merckling, N. Baboux, C. Plossu, O. Marty, M. El-Kazzi, G. Saint-Girons, B. Vilquin, G. Hollinger.

Appl. Phys. Lett. 91, 192909 (2007).

### 48. Local electronic transport through InAs/InP(001) quantum dots capped with a thin InP layer studied by an AFM conductive probe

M. Troyon, K. Smaali, M. Molinari, A. El Hdiy, G. Saint-Girons, G. Patriarche.

Semicond. Sci. Technol. 22, 755 (2007).

https://doi.org/10.1088/0268-1242/22/7/014

#### 49. Self-assembled Ge nanocrystals on BaTiO<sub>3</sub>/SrTiO<sub>3</sub>/Si(001)

L. Largeau, G. Patriarche G, G. Saint-Girons, G. Delhaye, G. Hollinger.

Appl. Phys. Lett. 92, 031904 (2008).

https://doi.org/10.1063/1.2837629

### 50. De-relaxation of plastically relaxed InAs/GaAs quantum dots during the growth of a GaAs encapsulation layer

G. Saint-Girons, I. Sagnes, G. Patriarche

J. Cryst. Growth 310, 536 (2008).

https://doi.org/10.1016/j.jcrysgro.2007.11.053

#### 51. Spontaneous compliance of the InP/SrTiO<sub>3</sub> heterointerface

G. Saint-Girons, C. Priester, P. Regreny, G. Patriarche, L. Largeau, V. Favre-Nicolin, G. Xu,

Y. Robach, M. Gendry, G. Hollinger

Appl. Phys. Lett. 92, 241907 (2008).

https://doi.org/10.1063/1.2944140

#### 52. Competition between InP and In<sub>2</sub>O<sub>3</sub> islands during the growth of InP on SrTiO<sub>3</sub>

G. Saint-Girons, P. Regreny, J. Cheng, G. Patrairche, L. Largeau, M. Gendry, G. Xu, Y. Robach, C. Botella, G. Grenet, G. Hollinger

J. Appl. Phys. 104, 033509 (2008).

https://doi.org/10.1063/1.2963484

#### 53. Epitaxial growth of high-κ oxides on silicon

C. Merckling, G. Saint-Girons, G. Delhaye, G. Patriarche, L. Largeau, V. Favre-Nicollin, M. El-Kazzi, P. Regreny, B. Vilquin, O. Marty, C. Botella, M. Gendry, G. Grenet, Y. Robach, G. Hollinger

Thin Solid Films, **517**, 197 (2008).

https://doi.org/10.1016/j.tsf.2008.08.165

### 54. Impact of a \gamma-Al2O3(001) barrier on LaAlO3 metal-oxide-semiconductor capacitor electrical properties

L. Becerra, C. Merckling, M. El-Kazzi, N. Baboux, B. Vilquin, G. Saint-Girons, C. Plossu, and G. Hollinger

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### 123. Stabilization of the ferroelectric phase in epitaxial $Hf_{1-x}Zr_xO_2$ enabling coexistence of ferroelectric and enhanced piezoelectric properties

T. Song, H. Tan, N. Dix, R. Moalla, J. Lyu, G. Saint-Girons, R. Bachelet, F. Sánchez, and I. Fina

ACS Applied Electronic Materials 3, 2106, (2021)

https://doi.org/10.1021/acsaelm.1c00122

### 124. Epitaxial Zn3N2 thin films by molecular beam epitaxy: Structural, electrical, and optical properties

P. John, M. Al Khalfioui, C. deparis, A. Welk, C. Licthensteiger, R. Bachelet, G. Saint-Girons, H. Rotella, M. Hugues, M. Grundmann and J. Zuniga-Perez J. Appl. Phys. **130**, 065104 (2021)

https://doi.org/10.1063/5.0057307

### 125. Thickness effect on ferroelectric properties of La-doped HfO2 epitaxial films down to 4.5 nm

T. Song, R. Bachelet, G. Saint-Girons, N. Dix, I. Fina, and F. Sánchez

J. Mater. Chem. C 9, 12224 (2021)

https://doi.org/10.1039/D1TC02512K

### 126. Impact of La Concentration on Ferroelectricity of La-Doped HfO2 Epitaxial Thin Films

T. Song, H. Tan, R. Bachelet, G. Saint-Girons, I. Fina, and F. Sánchez ACS Appl. Electron. Mater. **3**, 4809 (2021)

https://doi.org/10.1021/acsaelm.1c00672

### 127. Assessing the insulating properties of an ultrathin SrTiO<sub>3</sub> shell grown around GaAs nanowires with molecular beam epitaxy

N. Peric, T. Dursap, J. Becdelievre, M. Berthe, A. Addad; P. Rojo-Romeo, R. Bachelet, G. Saint-Girons, O. Lancry, S. Legendre, L. Biadala, J. Penuelas, B. Grandidier Nanotechnology **33**, 375702, (2022)

https://doi.org/10.1088/1361-6528/ac7576

#### 128. Tunable optical anisotropy in epitaxial phase-change VO<sub>2</sub> thin films

J. John, A. Slassi, J. Sun, Y. Sun, R. Bachelet, J. Pénuelas, G.Saint-Girons, R. Orobtchouk, S. Ramanathan, A. Calzolari, S. Cueff

Published online, Nanophotonics 11, 3913 (2022)

https://doi.org/10.1515/nanoph-2022-0153

### 129. Integration of Li<sub>4</sub>Ti<sub>5</sub>O<sub>12</sub> Crystalline Films on Silicon towards High-Rate Performance Lithionic Devices

S.D. Lacey, E. Gilardi, E. Müller, C. Merckling, G. Saint-Girons, C. Botella, R. Bachelet, D. Pergolesi, M. El Kazzi

ACS Appl. Mater. Interfaces 15, 1535, (2023)

https://doi.org/10.1021/acsami.2c17073

### 130. Ferroelectric Hf<sub>0.5</sub>Zr<sub>0.5</sub>O<sub>2</sub> films with improved endurance by low temperature epitaxial growth on seed layers

T. Song, R. Bachelet, G. Saint-Girons, I. Fina, F. Sánchez

Nanoscale 15, 5293, (2023)

https://doi.org/10.1039/D2NR05935E

### 131. Strain generated by the stacking faults in epitaxial SrO(SrTiO3)N Ruddlesden-Popper structures

G. Saint-Girons, C. Furgeaud, L. Largeau, A. Danescu, R. Bachelet and M. Bouras J. Appl. Cryst. **56**, 1426, (2023)

https://doi.org/10.1107/S1600576723006945

https://hal.science/hal-04220588

#### 132. Programming multilevel crystallization states in phase-change-material thin films

A. Taute, S. Al-Jibouri, C. Laprais, S. Monfray, J. Lumeau, A. Moreau, X. Letartre, N.

Baboux, G. Saint-Girons, L. Berguiga and S. Cueff

Optical Material Express 13, 3113, (2023)

https://doi.org/10.1364/OME.499809

https://hal.science/hal-04243325

#### 133. Integration of epitaxial LiNbO<sub>3</sub> thin films with silicon technology

A. Bartasyte, S. Oliveri, S. Boujnah, S. Margueron, R. Bachelet, G. Saint-Girons, D.

Albertini, B. Gautier, P. Boulet, E. Blanquet, V. Astié, and J.-M. Decams

Nanotechnology **35**, 175601, (2024)

https://doi.org/10.1088/1361-6528/ad1b98

https://hal.science/hal-04396804

#### 134. Sb<sub>2</sub>S<sub>3</sub> as a low-loss phase-change material for mid-IR photonics

A. Biegański, M. Perestjuk, R. Armand, A. Della Torre, C. Laprais, G. Saint-Girons, V.

Reboud, J.-M. Hartmann, J.-H. Tortai, A. Moreau, J. Lumeau, T. Nguyen, A. Mitchell, C.

Monat, S. Cueff and C. Grillet

Optical Materials Express 14, 862 (2024)

https://doi.org/10.1364/OME.511923

https://hal.science/hal-04625953

### 135. Absorption line broadening in atomic beams produced in a molecular beam epitaxy environment

R. Rousseau, J. Morville, C. Botella and G. Saint-Girons

Optics Express **23**, 40202 (2024)

https://doi.org/10.1364/OE.536538

#### 136. Reversible Single-Pulse Laser-Induced Phase Change of Sb2S3 Thin Films: Multi-Physics Modeling and Experimental Demonstrations

C. Laprais, C. Zrounba, J. Bouvier, N. Blanchard, M. Bugnet, A. Gassenq, Y. Gutiérrez, S. Vazquez-Miranda, S. Espinoza, P. Thiesen, R. Bourrellier, A. Benamrouche, N. Baboux, G.

Saint-Girons, L. Berguiga, S. Cueff

Adv. Optical Mater. 2024, 2401214

https://doi.org/10.1002/adom.202401214

https://hal.science/hal-04711821

### 137. Preferential orientations of FeRh nanomagnets deposited on a BaTiO3 epitaxial thin film

A. Reyes, G. Herrera, P. Capiod, D. Le Roy, V. Dupuis, I. Cañero-Infante, G. Saint-Girons, R. Bachelet, A. Resta, P. Ohresser, L. Martinelli, X. Weng, G. Renaud, and F. Tournus Phys. Rev. B **109**, 245510, (2024)

https://doi.org/10.1103/PhysRevB.109.245410

https://hal.science/hal-04621770

#### 138. Broadband cavity enhanced optical flux monitoring

R. Rousseau, C. Botella., J. Morville, M. Bounab, L. Berguiga, C. Furgeaud, R. Bachelet and G. Saint-Girons

J. Appl. Phys. 136, 185301 (2024)

doi: 10.1063/5.023543

#### 139. $Sr_{1+\delta}CrO_{2.8}$ epitaxial thin films

D. Han, B. Canut, G. Saint-Girons and R. Bachelet Cryst. Growth & Design **25**, 2809 (2025)

### 140. Spatially-Controlled Planar Czochralski Growth of Low-Loss Phase Change Materials for Programmable Photonics

F. Bentata, A. Taute, C. Laprais, R. Orobtchouk, E. Kempf, A. Gassenq, Y. Pipon, M. Calvo, S. Monfray, G. Saint-Girons, N. Baboux, H.S. Nguyen, X. Letartre, L. Berguiga, P. Genevet,

S. Cueff

Adv. Func. Mat., under revision

https://arxiv.org/html/2504.16603v1

### 141. Strong and engineerable optical anisotropy in easily integrable epitaxial SrO(SrTiO<sub>3</sub>)<sub>N</sub> Ruddlesden–Popper thin layers

M.O. Bounab, C. Furgeaud, S. Cueff, L. Berguiga, R. Bachelet, M. Bouras, L. Pedesseau, J. Even, L. Largeau, G. Saint-Girons

Adv. Opt. Mat., under revision

#### Conférences invitées

- 1. Croissance de boîtes quantiques d'In(Ga)As/GaAs par EPVOM sur pseudo-substrat de Ge/Si (100) pour la réalisation de composants émettant à 1,3 µm
- I. Sagnes, D. Bensahel, S. Bouchoule, Y. Campidelli, Y. Chriqui, O. Kermarrec, J-M. Moison, G. Patriarche, G. Saint-Girons

Journées IV-IV – grenoble 13-15 Janvier 2003.

- 2. InGaAs/GaAs sources monolithically grown by MOVPE on Ge/Si substrates I. Sagnes, Y. Chriqui, G. Saint-Girons, S. Bouchoule, D. Bensahel, O. Kermarrec, G. Isella, H. von Kaenel 2<sup>nd</sup> conference on Group IV Photonics, september 2005, Antwerpen (Belgium).
- 3. Non-conventional epitaxial relationship between InP nanocristallites and SrTiO3
- G. Saint-Girons

2<sup>nd</sup> French-Korean LIA workshop on Photonics and Nanostructures, june 14-15 2007, Ecully (France).

- 4. Monolithic integration of III-V and IV-IV semiconductors on Si using crystalline oxide buffers
- G. Saint-Girons

Lyon Tohoku workshop, february 8-9 2007, Lyon (France).

- 5. Molecular Beam Epitaxy of crystalline oxides on Si for C-MOS and for the monolithic integration of semiconductors on Silicon
- G. Saint-Girons, C. Merckling, M. El-Kazzi, L. Becerra, P. Regreny, G. Patriarche, L. Largeau, V. Favre-Nicollin, G. Hollinger.

Conference of the german society of physics, february 27-29 2008 – Berlin (Germany).

- 6. Epitaxie d'oxydes cristallins sur Si pour des applications C-MOS et pour l'intégration monolithique de semiconducteurs
- G. Saint-Girons

International Workshop on functional oxides, march 16-19 (2008) – Autrans (France).

- 7. Compliance spontanée à l'interface semiconducteur/oxyde crystallin : vers l'intégration d'hétérostructures III-V sur Silicium
- G. Saint-Girons, J. Cheng, C. Priester, P. Regreny, G. Patriarche, L. Largeau, V. Favre-Nicolin, M. Gendry, G. Grenet, G. Hollinger.

JNMO 2008, June 3-6 2008 – Oléron (France).

- 8. Monolithic integration of III-V and Ge on Si using compliant epitaxial oxide buffers
- G. Saint-Girons, J. Cheng, P. Regreny, G. Patriarche, L. Largeau, P. Rojo-Romeo, C. Seassal, G. Niu, B. Vilquin and G. Hollinger

Journées Nationales des technologies émergentes JNTE, 19-21 November 2008, Toulouse (France).

- 9. Integration of III-V on Si via the growth of oxides
- G. Saint-Girons, J. Cheng, P. Regreny, G. Patriarche, L. Largeau, P. Rojo-Romeo, C. Seassal, G. Niu, B. Vilquin and G. Hollinger

EUROMBE 2009 conference, march 8-11, (2009) – Zakopane (Poland).

10. Oxydes: croissance et contraintes

#### G. Saint-Girons

Ecole thématique "mécanique des nano-objets », march 14-19, (2010) – Autrans (France).

#### 11. Epitaxial systems conbining oxides and semiconductors

G. Saint-Girons, B. Vilquin, J. Cheng, G. Niu, B. Gobaut, A. Chettaoui, Y. Shi, J. Penuelas, P. Regreny, M. Gendry, L. Largeau, G. Patriarche; G. Grenet, G. Hollinger Transalp'Nano 2010 conference, june 3-5, (2010) – Como (Italy).

#### 12. Epitaxial systems conbining oxides and semiconductors

G. Saint-Girons, B. Vilquin

MBE 2010 conference, august 22-27, (2010) – Berlin (Germany).

#### 13. Epitaxial growth of cristalline oxides for nanoelectronics

G. Saint-Girons, G. Niu, Y. Shi, B. Vilquin, J. Penuelas, G. Grenet and G. Hollinger International conference on materials, energy and environment, May 10-11 2012, Toledo (USA).

### 14. Epitaxy of functional heterostructures combining oxides and semiconductors, and application perspectives for the fabrication of novel integrated photonic devices

G. Saint-Girons

2012 EMN meeting, April 16-20, 2012, Orlando (USA).

#### 15. Integration of functional oxides with semiconductors

R. Bachelet, G. Niu, L. Louahadj, P. Regreny, B. Vilquin, P. de Coux, B. Warot-Fonrose, I. Fina, V. Skumryev, J. Fontcuberta, F. Sanchez, G. Saint-Girons 2012 collaborative conference on crystal growth, Dec 11-14(2012), Orlando (USA).

#### 16. Functional oxide nanostructures for energy harvesting

R. Bachelet, N. Barrett, A. Borowiak, D. Cazoir, F. Gaillard, B. Gautier, J. Leroy, Q. Liu, L.Louahadj, C. Malhaire, O. Marconot, S. Nassreddine, G. Niu, J. Penuelas, J. Pezard, L. Piccolo, M.Piquemal, E. Puzenat, Y. Robach, P. Rojo-Romeo, G. Saint-Girons, B. Vilquin, J. Wang

2012 collaborative conference on crystal growth, Dec 11-14(2012), Orlando (USA).

#### 17. Weakly interacting epitaxial systems: the semiconductor/SrTiO<sub>3</sub> case

G. Saint-Girons, A. Danescu, B. Gobaut, J. Penuelas, G. Grenet, G. Renaud, N. Blanc, V. Favre-Nicollin, M. El-Kazzi, F. Sirotti, M. Silly

43<sup>rd</sup> IEEE SISC conference, December 6-8, 2012, San Diego (USA).

#### 18. Systèmes épitaxiés faiblement liés, le cas semiconducteur/SrTiO<sub>3</sub>

G. Saint-Girons, A. Danescu, B. Gobaut, J. Penuelas, G. Grenet, G. Renaud, N. Blanc, V. Favre-Nicollin, M. El-Kazzi, F. Sirotti, M. Silly

Journées surfaces et interfaces 2013, 30/01-01/12 2013, Orléans (France).

#### 19. Integration of functional oxides with semiconductors

R. Bachelet, G. Niu, S. Yin, L. Louahadj, L. Mazet, I. Fina, V. Skumryev, P. de Coux, B. Warot-Fonrose, L. Largeau, P. Regreny, C. Dubourdieu, B. Vilquin, G. Le Rhun, E. Defaÿ, G. Agnus, P. Lecoeur, J. Fontcuberta, F. Sanchez, G. Saint-Girons

Colloque annuel du GDR pulse, 3-5 juillet 2013, Aix en Provence (France).

20. Silicon CMOS compatible transition metal oxide technology for boosting highly

#### integrated photonic devices with disruptive performance.

P. Sanchis, L. Sánchez, P. Castera, A. Rosa Escutia, A. M. Gutierrez, A. Brimont, G. Saint-Girons, R. Orobtchouk, S. Cueff, P. Rojo-Romeo, R. Bachelet, P. Regreny, B. Vilquin, C. Dubourdieu, X. Letartre, G. Grenet, J. Penuelas, X. Hu, L. Louahadj, J.-P. Locquet, L. Zimmermann, C. Marchiori, S. Abel, J. Fompeyrine, A. Håkansson

16th International Conference on Transparent Optical Networks - ICTON (July 2014). Graz

16th International Conference on Transparent Optical Networks - ICTON (July 2014). Graz (Austria).

21. Monolithic integration of epitaxial BaTiO3 on Si and SiGe for ferroelectric devices L. Mazet, R. Bachelet, G. Saint-Girons, D. Albertini, B. Gautier, M. Frank, J. Jordan-Sweet, I. Lauer, V. Narayanan, M. Hytch, S. Schamm-Chardon, C. Dubourdieu 61st AVS International Symposium, nov 9-14 2014, Baltimore (USA).

#### 22. Integration of functional oxides on silicon for nanoelectronics and energy

R. Bachelet, L. Louahadj, L. Mazet, R. Moalla, G. Niu, P. Regreny, B. Vilquin, C. Dubourdieu, J. Fontcuberta, F. Sanchez, G. Saint-Girons

International Conference on Materials and Characterization Techniques (ICMCT), March 10 – 12, 2014, Chennai, (India).

#### 23. Epitaxy of ferroelectric complex oxides on semiconductors for field-effect devices

L. Mazet, R. Bachelet, G. Saint-Girons, L. Louahadj, D. Albertini, B. Gautier, J. Jordan-Sweet, M. Frank, V. Narayanan, M. Hytch, S. Schamm-Chardon, C. Dubourdieu

10th International Conference on Physics of Advanced Materials, sept 22-28 2014, Iasi (Romania).

### 24. Catalyse par le Sr de de la cristallisation de SrTiO<sub>3</sub> lors des premiers stades de sa croissance sur Si

G. Saint-Girons, R. Bachelet, G. Grenet, J. Penuelas, L. Louahadj, A. Carretero-Genevrier, B. Canut, M. Silly, F. Sirotti

Colloque annuel du GDR PULSE, 27-29 octobre 2014, Toulouse (France).

### 25. Heterostructures combining functional oxides and semiconductors for integrated photonics

G. Saint-Girons, S. Cueff, B. Meunier, X. Hu, L. Louahadj, L. Mazet, R. Orobtchouk, P. Rojo-Romeo, R. Bachelet, B. Vilquin, P. Regreny, N. Chauvin, G. Grenet, J. Penuelas, A. Danescu, C. Dubourdieu, X. Letartre, G. Renaud, V. Favre-Nicolin, N. Blanc, T. Zhou, M. Silly, F. Sirotti, L. Largeau, G. Agnus, V. Pillard, D. Le Bourdais, P. Lecoeur

Workshop "Les oxydes pour l'optique et la photonique", 8-9 décembre 2014, Meudon, (France).

#### 26. Complex oxides on semiconductors for nanoelectronic applications

L. Mazet, R. Bachelet, G. Saint-Girons, M. Hÿtch, S. Schamm-Chardon, C Dubourdieu TMS 2015 conference, 15-19 mars 2015, Orlando, (USA).

#### 27. Molecular beam epitaxy of ferroelectric complex oxides on silicon

C. Dubourdieu, L. Mazet, S. Yang, R. Cours, R. Bachelet, G. Saint-Girons, C. Magen, M. Hytch, S. Kalinin and S. Schamm Chardon

INFOS 2015 conference, 30 juin – 2 juillet 2015, Udine, (Italie).

#### 28. Integration of functional oxides on SOI for agile silicon photonics

P. Rojo Romeo, X. Hu, S. Cueff, R. Orobtchouk, B. Vilquin, R. Bachelet, G. Grenet, C. Dubourdieu, P. Regreny, G. Saint-Girons, P. Castera, A.M. Gutierrez, N. Sanchez, T. Angelova,

#### P. Sanchis, S. Abel, J. Fompeyrine

ICTON 2015 conference, 5-9 juillet 2015, Budapest, (Hongrie).

### 29. Heterostructures combining functional oxides and semiconductors for integrated photonics

G. Saint-Girons

Workshop MNP 2015, 2-3 décembre 2015, Besançon, (France).

#### 30. Perovskite Oxide MEMS: Strain Control and Sensor Applications

P. Lecoeur, D. Le Bourdais, G. Agnus, T. Maroutian, S. Matzen, L. Largeau, G. Saint-Girons, B. Vilquin, E. Lefeuvre

MRS 2015 Fall Meeting, 29 novembre – 4 décembre 2015, Boston (USA).

#### 31. Growth of core (GaAs) / shell (functional oxide) nanowires

X. Guan, J. Becdelievre, B. Meunier, A. Benali, G. Saint-Girons, R. Bachelet, P. Regreny, C. Botella, G. Grenet, N. P. Blanchard, X. Jaurand, M. G. Silly, F. Sirotti, N. Chauvin, M. Gendry, J. Penuelas

EMN 2016 conference on Nanowires, may 16-19 2016, Amsterdam (Netherlands).

#### 32. Functional oxides for optical devices

G. Saint-Girons, S. Cueff, B. Meunier, R. Bachelet, J. Penuelas, R. Orobtchouk, P. Rojo-Romeo, B. Vilquin, P. Regreny, G. Grenet, L. Largeau<sup>2</sup>, G. Agnus, V. Pillard, D. Le Bourdais, P. Lecoeur, P. Castera, A. Rosa, A.M. Gutierrez, T. Angelova, A. Griol, P. Sanchis, S. Abel, J. Fompeyrine

E-MRS 2016 Fall Meeting, sept. 19-22 2016, Warsaw (Poland).

#### 33. Hybrid silicon-ferroelectric oxide platform for tunable nanophotonics on silicon

S. Cueff, P. Castera, A.M. Gutierrez, P. Rojo Romeo, R. Orobtchouk, B. Wague, B. Vilquin, P. Regreny, A. Rosa, T. Angelova, A. Griol, P. Sanchis, G. Saint-Girons ICTON 2016 conference, 10-14 juillet 2016, Trento, (Italy).

#### 34 Oxydes fonctionnels intégrés sur Si pour des applications en énergie et photonique

R. Bachelet, M. Apreutesei, R. Moalla, B. Meunier, S. Cueff, P. Regreny, B.

Vilquin, P. Rojo-Romeo, R. Orobtchouk, J. Penuelas, G. Grenet, A. Carretero-Genevrier, J. Gazquez, N. Baboux, R. Debord, S. Pailhès, G. Saint-Girons JNMO 2016, 30 mai – 1<sup>er</sup> juin 2016, Les Issambres, (France).

#### 35. Growth of hybrid GaAs core / shell nanowires

X. Guan, J. Becdelievre, G. Saint-Girons, R. Bachelet, P. Regreny, C. Botella, G. Grenet, A. Danescu, B. Vilquin, P. Rojo-Romeo, N. Chauvin, N. P. Blanchard, M. G. Silly, F. Sirotti, M. Gendry, J. Penuelas

Colloque annuel du GDR PULSE, 18-22 juillet 2016, Marseille (France).

### 36. Heterogeneous oxide/semiconductor systems: some specific features of their crystal growth, how could in-situ TEM contribute to their study

G. Saint-Girons

Inauguration du microscope Nanomax, 12 juillet 2017, Ecole polytechnique, Palaiseau (France)

#### 37. Contrôle dynamique de la lumière par des matériaux fonctionnels

S. Cueff, R. Orobtchouk, P. Rojo-Romeo, B. Vilquin, G. Saint-Girons, A. M. Gutierrez, P. Castera, Á. Rosa, P. Sanchis, Y. Zhou, S. Ramanathan, D. Li, J. Kurvits, R. Zia Workshop du GDR Ondes, 24 octobre 2017, Sophia-Antipolis, Nice (France)

### 38. Engineering the properties of functional oxides and integrating them on Si and GaAs thanks to molecular beam epitaxy

G. Saint-Girons, M. Bouras, S. Cueff, R. Bachelet, D. Han, J. Penuelas, G. Grenet, P. Regreny, N. Chauvin, L. Largeau

EMRS-2018 Spring meeting, June 18-22, 2018, Strasbourg, France.

### 39. Mesure des flux pendant la croissance épitaxiale : balance à quartz, spectrométrie de masse, spectrométrie par impact d'électrons

G. Saint-Girons

Atelier du GDR PULSE, october 01-03, 2018, Toulouse, France.

#### 40. Epitaxial integration of nanostructured functional oxides on silicon by solution chemistry

J.M. Vila-Fungueiriño, A. Gómez, G. Saint-Girons, C. Magén, J. Gázquez, R. Bachelet, M. Gich, F. Rivadulla, A. Carretero-Genevrier

EMRS-2018 Spring meeting, June 18-22, 2018, Strasbourg, France.

#### 41. Epitaxial ferroelectric doped HfO<sub>2</sub> thin films on Si(001)

T. Song, J. Lyu, S. Estandía, J. Gàzquez, G. Saint-Girons, R. Bachelet, I. Fina and F. Sánchez Workshop virtuel sur l'épitaxie des oxydes (EPIDOX), November 17-19<sup>th</sup>, 2021

### 42. Oxide MBE: challenges and opportunities - Integration on semiconductors, complex solid solutions and ultimate superlattice

R. Bachelet and G. Saint-Girons

Journées Nationales du GDR OXYFUN, April 1-8, 2022 Guéthary, (France)

#### 43. Advanced optical flux monitoring to control thin layer deposition processes

R. Rousseau, C. Botella, J. Morville and G. Saint-Girons

Workshop du COST OPERA "From Epitaxial Materials towards Technological Transfer", August 29-31 2023 Paris Saclay, France

https://hal.science/hal-04220588

#### 44. Programmable Multilevel Nanophotonics with Phase-Change Materials

F. Bentata, C. Laprais, S. Monfray, N. Baboux, X. Letartre, G. Saint-Girons, P. Genevet, L. Berguiga and S. Cueff

Metafun 2024 conference, July 23-26 2024, Palermo (Italy)

### 45. Programmable Nanophotonics with Phase-Change Materials: Towards Multilevel Tunability and Low-Loss devices

F. Bentata, C. Laprais, N. Baboux, P. Genevet, S. Monfray, G. Saint-Girons, X. Letartre, L.

Berguiga and S. Cueff AES 2024 conference, June 25-28 2024, Roma (Italy)

### 46. Nanophotonique programmable multi-niveaux à base de matériaux à changement de phase

C. Laprais, F. Bentata, A. Taute, N. Baboux, X. Letartre, G. Saint-Girons, S. Monfray, P. Genevet, L. Berguiga and S. Cueff

Congrès "Optique Normandie 2024" de la SFO, 1-5 juillet 2024, Rouen (France)

#### 47. Projet PIA EquipEx+ Nanofutur @INL

P. Regreny, J.B. Goure, C. Botella, C. Furgeaud, R. Rousseau, R. Bachelet and G. Saint-Girons 3ème édition des journées thématiques Renatech "CROISSANCE CRISTALLINE", 7-8 novembre 2024, Toulouse (France)

#### 48. Cavity-enhanced optical flux monitoring for the growth of oxide materials

R. Rousseau, C. Botella, J. Morville, M. Bounab, L. Berguiga, C. Furgeaud, R. Bachelet and G. Saint-Girons

Conférence plénière du GDR MATEPI, 3-6 novembre 2025, IEMN, Lille (France)

#### 49. Comparison of oxide and semiconductor epitaxy and oxide/semiconductor integration

G. Saint-Girons

MATEPI summer school on Epitaxy, 22-27 june 2025, Porquerolles (France)

#### Séminaires invités

### 1. Boîtes quantiques In(Ga)As/GaAs épitaxiées par EPVOM pour l'émission autour de 1,3 µm sur GaAs

G. Saint-Girons, G. Patriarche, B. Sermage, J.M. Moison, I. Sagnes Séminaire donné au CEM2, Novembre 2002, Montpellier.

#### 2. MOVPE grown In(Ga)As/GaAs QDs for 1.3 µm emission

G. Saint-Girons, I. Sagnes

Séminaire donné à l'Imperial College (London, England), Novembre 2002.

#### 3. MOVPE grown In(Ga)As/GaAs QDs for 1.3 µm emission

G. Saint-Girons, I. Sagnes

Séminaire donné Bookham (Northampton, England), Novembre 2002.

#### 4. MOVPE grown In(Ga)As/GaAs QDs for 1.3 µm emission

G. Saint-Girons, I. Sagnes

Séminaire donné à University of Sheffield (Sheffield, England), Novembre 2002.

5. Boîtes quantiques In(Ga)As/GaAs épitaxiées par EPVOMG. Saint-Girons, A. Michon, G. Patriarche, I. Sagnes, G. BeaudoinSéminaire donné au LPM (INSA de Lyon), mars 2005.

#### 6. EPVOM: boîtes quantiques et hétérostructures GaAs/Si

G. Saint-GironsSéminaire donné au LEOM (Ecole Centrale de Lyon) septembre 2005.

#### 7. Boîtes quantiques de semiconducteurs III-V épitaxiées par EPVOM

G. Saint-Girons

Séminaire donné au LPN le 10 mai 2006.

#### 8. Monolithic integration of crystalline oxides and III-V heterostructures on silicon

G. Saint-Girons

Séminaire donné à l'IHP, Franckfurt/Oder (germany) le 16 septembre 2009.

#### 9. Systèmes épitaxiés combinant oxydes et semiconducteurs

G. Saint-Girons

Séminaire donné au LPN le 10 juin 2010.

#### 10. Systèmes épitaxiés combinant oxydes et semiconducteurs

G. Saint-Girons

Séminaire donné au CRHEA le 5 février 2013.

#### 11. Epitaxial systems combining oxides and semiconductors

G. Saint-Girons

Séminaire donné à l'UMR Thalès le 12 septembre 2019

### 12. Engineering the dielectric properties of functional oxides and integrating them on semiconductor platforms thanks to oxide molecular beam epitaxy

G. Saint-Girons Séminaire donné à l'IMEC le 7 octobre 2019

#### Interventions dans des conférences internationales

1. Optical and structural properties of 1,3 μm emitting LP-MOVPE grown quantum dots G. Saint-Girons, A. Mereuta, G. Patriarche, J.M. Gérard, I. Sagnes Indium Phosphide and Related Materials conference, Williamsburg, USA, IPRM 2000.

#### 2. GaAsSbN: a material for 1.3-1.55 µm emission

G.Ungaro, I. Sagnes, G. Le-Roux, L. Largeau, G. Patriarche, G. Saint-Girons, J.C. Harmand Indium Phosphide and Related Materials conference, Williamsburg, USA, IPRM 2000.

### 3. Influence of the anneal temperature on the optical properties of 1,3 $\mu$ m emitting quantum dots

G.Saint-Girons, A. Mereuta, G. Patriarche, J.M. Gérard, I. Sagnes European Material Research Society conference, Optical Materials 17, 263, (2001).

### 4. MOVPE growth and characterization of 1,3 $\mu$ m emitting InAs quantum dots (QDs) for laser application on GaAs

G. Saint-Girons, J.M. Gérard, A. Mereuta, G. Patriarche, L. Largeau, J. Coelho, I. Sagnes International Workshop on Novel Gain Materials, COST 268, Würzburg (2001).

### 5. MOVPE growth and characterization of 1.3 µm emitting InAs quantum dots for laser application on GaAs

G. Saint-Girons, J.M. Gérard, A. Mereuta, G. Patriarche, L. Largeau, J. Coelho, I. Sagnes International Workshop on Novel Gain Materials, COST 268, Lecce (2001).

#### 6. (InGa)(NAs)/GaAs structures emitting in $1-1.6 \mu m$ wavelength range

A. Mereuta, G. Saint-Girons, S. Bouchoule, I. Sagnes, F. Alexandre, G. Le Roux, J. Decobert, A. Ougazzaden

E-MRS 2000 conference, Optical Materials. 17, 185, (2001).

#### 7. Micromachined airgap cavities for widely tunable 1.55 µm VCSEL

F. Riemenscheider, J. Pfeiffer, H. Halbritter, M. Aziz, A. Mereuta, G. Saint-Girons, I. Sagnes, P. Meissner

Workshop « Optical MEMS and Integrated Optics », university of Dortmund, (2001).

#### 8. InP/AlGaInAs Distributed Bragg Reflector: a high potential for 1.55 µm VCSELs

A. Mereuta, G. Le Roux, C. Mériadec, L. Largeau, G. Saint-Girons, C. Symonds, J.L. Oudar, and I. Sagnes

International conference on Materials science and condensed matter physics, Chisinau Moldavie, MSCMP (2001).

### 9. <500 fs soliton pulse in passively mode-locked surface-emitting laser with 100-mW average power

A. Garnache, S. Hoogland, A.C. Tropper, I. Sagnes, G. Saint-Girons, J.S. Roberts CLEO conference, Long-Beach USA, (2002).

### 10. Lasing operation under pulsed optical pumping of a 1,55 µm external-cavity VCSEL using an InP/AlGaInAs bottom Bragg reflector

C. Symonds, G. Saint-Girons, I. Sagnes, A. Mereuta, J.L. Oudar Indium Phosphide and Related Materials conference, Stockholm, Sweden, IPRM (2002).

#### 11. Monolithic Tunable InP-based Vertical Cavity Surface Emitting Laser

J.L. Leclercq, P. Regreny, P. Viktorovitch, A. Bakouboula, T. Benyattou, I. Sagnes, G. Saint-Girons, C. Mériadec, A. Mereuta, A. Plais, J. Jacquet DTIP conference, Cannes (2002).

### 12. Silicon on insulator and SiGe waveguide photodetectors with Ge/Si self-assembled islands

M. Elkurdi, P. Boucaud, S. Sauvage, G. Saint-Girons, I. Sagnes, O. Kermarrec, Y. Campidelli, D. Bensahel

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### 13. Electromodulation of the interband and intraband absorption of Ge/Si self assembled islands

M. Elkurdi, P. Boucaud, G. Fishman, S. Sauvage, O. Kermarrec, Y. Campidelli, D. Bensahel, G. Saint-Girons, I. Sagnes

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### 14. Sub-500-fs soliton-like pulse in a passively mode-locked broadband surface-emitting laser with 100-mW average power

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### 15. MOVPE growth and characterizations of long-wavelength emitting quantum dots based lasers

G. Saint-Girons, A. Garnache, G. Patriarche and I. Sagnes Indium-Phosphide-and-Related-Materials 2003 (Santa Barbara CA). Paper TuB2.2

### 16. A new kind of fast quantum-well Semiconductor Saturable-Absorber Mirror with low losses for ps pulse generation

A. Garnache, B. Sermage, R. Teissier, G. Saint-Girons and I. Sagnes Indium-Phosphide-and-Related-Materials 2003 (Santa Barbara CA). Paper WB1.4

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A. Garnache, B. Sermage, R. Teissier, G. Saint-Girons and I .Sagnes IEEE CLEO Europe EQEC 2003 (Munich, DE). Paper CC8-2-WED

### 18. Material and optical properties of GaAs grown on (001) Ge/Si pseudo-substrate for the monolithic integration of light emitting devices on silicon

Y. Chriqui, L. Largeau, G. Patriarche, G. Saint-Girons, S. Bouchoule, D. Bensahel, Y. Campidelli, O. Kermarrec, I. Sagnes

E-MRS conference (2004), Strasbourg

### 19. Room Temperature laser operation of strained InGaAs/GaAs QW structure monolithically grown by MOVCD on LE-PECVD Ge/Si virtual substrate.

S. Bouchoule, Y. Chriqui, G. Saint-Girons, G. Isella, H. von Kaenel, I. Sagnes E-MRS conference, mai 2004, Strasbourg

#### 20. 1.55 µm VCSELs with InP/air-gap distributed bragg reflectors

M. Strassner, P. Regreny, S. Bouchoule, N. Chitica, I. Sagnes, G. Saint-Girons, J. Jacquet, and J.-L. Leclercq

Indium-Phosphide-and-Related Materials, juin 2004, Kagoshima (Japon)

### 21. Room Temperature laser operation of strained InGaAs/GaAs QW structure monolithically grown by MOVCD on LE-PECVD Ge/Si virtual substrate.

Y. Chriqui, G. Saint-Girons, S. Bouchoule, G. Isella, H. von Kaenel, I. Sagnes MRS spring meeting conference, avril 2004, San Francisco (USA)

#### 22. Material and optical properties of GaAs grown on (001) Ge/Si pseudo-substrate

Y. Chriqui, L. Largeau, G. Patriarche, G. Saint-Girons, S. Bouchoule, D. Bensahel, Y. Campidelli, O. Kermarrec, I. Sagnes

MRS spring meeting conference, avril 2004, San Francisco (USA)

### 23. Photoluminescence probing of non-radiative channels in hydrogenated In(Ga)As/GaAs quantum dots

G. Saint-Girons, A. Lemaître, V. Navarro-Paredes, G. Patriarche, E.V.K. Rao, I. Sagnes and B. Theys.

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#### 24. Photonics, Electronics and Silicon-Germanium :a possible convergence?

O. Kermarrec, Y. Campidelli, D. Bensahel, S. David, M. El kurdi, P. Boucaud, Y. Chriqui, S. Bouchoule, G. Saint-Girons and I. Sagnes

ECS conference, 3-8 October 2004, Honolulu (Hawaï)

# 25. Investigation of Buried GaAs/Ge/Si (001) Interfaces using Anomalous X-ray Reflectivity. E. Wintersberger, J. Stangl, T. Schuelli, M. Meduna, G. Bauer, Y. Chriqui, L. Largeau, I. Sagnes, G. Saint-Girons, D. Bensahel, Y. Campidelli and O. Kermarrec

MRS Fall meeting conference,  $29/11 - 3/12\ 2004$ , Boston (USA)

#### 26. Stess-engineered orderings of self-assembled III-V semiconductor nanostructures

J. Coelho, G. Patriarche, F. Glas, I. Sagnes and G. Saint-Girons Congrès EXMATEC Montpellier, 1-4 juin 2004.

### 27. Dynamics of carrier –capture processes in Ga<sub>0.47</sub>In<sub>0.53</sub>As/InP near-surface quantum wells C. Symonds, J. Mangeney, G. Saint-Girons, I. Sagnes, K. Meunier, A. Garnache

Indium-Phosphide-and-Related Materials, may 2005, Glasgow (Scotland)

### 28. Microphotoluminescence around 1.5 $\mu$ m from a Single InAs/InP(001) Quantum Dot grown by MOVPE.

N. Chauvin, A. Michon, I. Sagnes, G. Patriarche, G. Beaudoin, G. Brémond, C. Bru-Chevallier and G. Saint-Girons

CLEO - 21 to 26 may 2006 - Long Beach (USA)

### 29 InAs/InP(001) quantum dots and quantum sticks grown by Metalorganic Vapor Phase Epitaxy: shape, anisotropy and formation process.

A. Michon, G. Patriarche, I. Sagnes, G. Beaudoin and G. Saint-Girons Quantum Dots 2006 conference – 2 to 5 may 2006 – Chamonix (France) 30. Thermodynamic analysis of the shape, anisotropy and formation process of InAs/InP(001) quantum dots and quantum sticks grown by Metalorganic Vapor Phase Epitaxy.

G. Saint-Girons, A. Michon, I. Sagnes, G. Beaudoin and G. Patriarche Nanosea 2006 conference – 2 to 7 july 2006 - Aix en Provence (France)

31. Thermodynamic analysis of the shape, anisotropy and formation process of InAs/InP(001) quantum dots and quantum sticks grown by Metalorganic Vapor Phase Epitaxy.

G. Saint-Girons, A. Michon, I. Sagnes, G. Beaudoin and G. Patriarche ICPS 2006 conference – 24 to 28 july 2006 – Vienna (Austria).

### 32. MBE Growth and relaxation of Al<sub>2</sub>O<sub>3</sub> on Si

C. Merckling, M. El-Kazzi, G. Delhaye, V. Favre-Nicolin, O. Marty, Y. Jugnet, L. Largeau, G. Patriarche, G. Saint-Girons, Y. Robach, M. Gendry, G. Grenet, G. Hollinger E-MRS conference 2006 – may 29 to june 1<sup>st</sup> 2006 – Nice (France)

33. InAs/InP(001) Quantum Dots And Quantum Sticks Grown By MOVPE: Shape, Anisotropy And Formation Process

G. Saint-Girons, A. Michon, I. Sagnes, G. Beaudoin, and G. Patriarche AIP Conf. Proc. **893**, 71 (2007)

34. XPD investigation of heterostructures of thin epitaxial oxides: LaAlO<sub>3</sub>/SrTiO<sub>3</sub>(001) and y-Al<sub>2</sub>O<sub>3</sub>/Si

M. El Kazzi, C.Merckling, G. Delhaye, G. Saint-Girons, G.Grenet, G. Hollinger E-MRS conference 2006 – may 28 to june 1st 2006 – Nice (France)

35. Development of robust interfaces based on crystalline  $\gamma$ -Al<sub>2</sub>O<sub>3</sub>(001) for subsequent deposition of amorphous high- $\kappa$  oxides

C. Merckling, M. El-Kazzi, L. Beccera, L. Largeau, G. Patriarche, G. Saint-Girons, G. Hollinger

INFOS 2007 conference - june 20 to 23 2007 – Athen, greece

### 36. Epitaxial growth of high-κ oxides on silicon

C. Merckling, G. Saint-Girons, G. Delhaye, G. Patriarche, L. Largeau, V. Favre-Nicollin, M. El-Kazzi, P. Regreny, B. Vilquin, O. Marty, C. Botella, M. Gendry, G. Grenet, Y. Robach and G. Hollinger

ICSI 5 conference, may 20 to 25 2007, Marseille, France

37. XPD and RHEED investigation of thin epitaxial Al<sub>2</sub>O<sub>3</sub>/Si(111) and Al<sub>2</sub>O<sub>3</sub>/Si(001)

M. El Kazzi, C. Merckling, G. Saint-Girons, G. Grenet, G. Hollinger ICSI 5 conference, may 20 to 25 2007, Marseille, France

38. Epitaxial growth of LaAlO3 on Si(001) using interface engineering

C. Merckling, G. Delhaye, M. El-Kazzi, S. Gaillard, Y. Rozier, L. Rapenne, B. Chenevier, O. Marty, G. Saint-Girons, M. Gendry, Y. Robach, G. Hollinger WODIM 2007 conference, june 26 to 28 2007 – Santa-Tecla (Italy)

## 39. Luminescence properties of single InAs/InP(001) quantum dots grown by solid source molecular beam epitaxy

E. Dupuy, N. Pauc, N. Chauvin, G. Patriarche, P. Regreny, G. Saint-Girons, D. Drouin, V. Aimez, C. Bru-Chevallier, M. Gendry, D. Morris CSTC 2007, 14-17 Aout 2007, Montréal (Canada)

## 40. Properties of single InAs/InP(001) quantum dots grown by solid source molecular beam epitaxy

E. Dupuy, N. Pauc, N. Chauvin, G. Patriarche, P. Regreny, G. Saint-Girons, D. Drouin, V. Aimez, G. Bremond, C. Bru-Chevallier, D. Morris, M. Gendry EuroMBE 2007, 5-7 Mars 2007, Grenade (Espagne)

### 41. Optimization of the MBE growth conditions of crystalline SrTiO<sub>3</sub> on Si (001)

G. Delhaye, M. El Kazzi, C. Merckling, X. Genzhao, G. Saint-Girons, M. Gendry, L. Largeau, G. Patriarche, G. Hollinger, Y. Robach ICSI5, 20-25 may 2007, Marseille.

## 42. Monolithic integration of InP based heterostructures on silicon using crystalline Gd<sub>2</sub>O<sub>3</sub> buffers.

G. Saint-Girons, P. Regreny, J. Cheng, G. Hollinger, L. Largeau, G. Patriarche IPRM 2008 conference, may 25 to 29, (2008) – Versailles (France)

## 43. Strategies for CMOS low equivalent oxide thickness achievement with high- $\kappa$ oxides grown on Si(001) by MBE

L. Becerra, N. Baboux, C. Plossu, C. Merckling, M. El-Kazzi, G. Saint-Girons, B. Vilquin, G. Hollinger

MRS2008 – Spring meeting, march 24-28, (2008) – San Francisco (USA).

## 44. Epitaxial growth of high- $\kappa$ oxides on silicon for advanced CMOS: LaAlO3, Gd2O3, $\gamma$ -Al2O3

C. Merckling, M. El-Kazzi, L. Becerra, G. Saint-Girons, G. Delhaye, G. Patriarche, L. Largeau, V. Favre-Nicolin, N. Baboux, C. Plossu, O. Marty, and G. Hollinger WODIM 2008, june 23-25, (2008) – Bas Saarow (Germany)

### 45. Impact of a γ-Al<sub>2</sub>O<sub>3</sub>(001) barrier on LaAlO<sub>3</sub> MOS capacitors electrical properties

L. Becerra, C. Merckling, M. El-Kazzi, N. Baboux, B. Vilquin, G. Saint-Girons, C. Plossu, and G. Hollinger

WODIM 2008, june 23-25, (2008) – Bas Saarow (Germany)

### 46. Integration of functional oxides on STO buffered silicon

B. Vilquin, G. Niu, G. Delhaye, G. Saint-Girons, Y. Robach, B. Canut, G. Hollinger, B. Blein, S. Autier-Laurent, P. Lecoeur

Trans' Alp Nano 2008 conference, october 27-29, 2008, Lyon (France)

# 47. Monolithic integration of III-V heterostructures on silicon using crystalline oxide buffers J. Cheng, G. Saint-Girons, P. Regreny, G. Patriarche, L. Largeau, M. Gendry, G. Hollinger Trans'Alp Nano 2008 conference, october 27-29, 2008, Lyon (France)

## 48. Synchrotron radiation and conventional X-ray source photoemission studies of $\gamma$ -Al<sub>2</sub>O<sub>3</sub> thin films grown on Si(111) and Si(001) by molecular beam epitaxy

M. El-Kazzi, C. Merckling, G. Grenet, G. Saint-Girons, M. Silly, F. Sirotti, G. Hollinger MRS Spring meeting 2009, 13-17 April 2009, San-Francisco (USA)

### 49. Growth temperature dependence of epitaxial Gd<sub>2</sub>O<sub>3</sub> films on Si(111)

G Niu, B. Vilquin, L. Becerra, S. Pelloquin, G. Saint-Girons and G. Hollinger INFOS 2009 conference, 29 juin-1 juillet 2009, Cambridge (UK)

## 50. Molecular beam deposition of LaAlO<sub>3</sub> on silicon for sub-22 nm CMOS technological nodes: toward a perfect control of the oxide/Si heteorinterface

S. Pelloquin, L. Becerra, G. Saint-Girons, C. Plossu, N. Baboux, D. Albertini, P. Regreny, G. Grenet, G. Hollinger

INFOS 2009 conference, 29 juin-1 juillet 2009, Cambridge (UK)

### 51. Direct epitaxial growth of InP based heterostructures on SrTiO<sub>3</sub>/Si templates

G. Saint-Girons, J. Cheng, A. Chettaoui, B. Gobaut, J. Penuelas, P. Regreny, M. Gendry, L. Largeau, G. Patriarche, G. Hollinger

EMRS 2010 spring meeting, june 7-11 (2010), Strasboug (France)

### 52. Direct epitaxial growth of SrTiO<sub>3</sub> on Si: interface and crystallization

G. Niu, W.W. Peng, G. Saint-Girons, J. Penuelas, P. Roy, J.B. Brubach, J-L. Maurice, G. Hollinger, and B. Vilquin

EMRS 2010 spring meeting, june 7-11 (2010), Strasboug (France)

### 53. Structural properties of III-V quantum dots on SrTiO<sub>3</sub>/Si

J. Penuelas, B. Gobaut, J. Cheng, A. Chettaoui, L. Largeau, G. Patriarche, G. Hollinger, G. Saint-Girons

EMRS 2010 spring meeting, june 7-11 (2010), Strasboug (France)

## 54. Chemical bonding at Ge/SrTiO3 interface versus Ge growth temperature and surface stoechiometry

M. El Kazzi, G. Grenet, J. Penuelas, B. Gobaut, M. Thomasset, M. Silly, F. Sirotti, G. Saint-Girons

EMRS 2010 spring meeting, june 7-11 (2010), Strasboug (France)

## 55. Electrical characteristics of $Gd_2O_3$ films on Si(111): impact of growth temperature and post-deposition annealing

G. Niu, B. Vilquin, N. Baboux, G. Saint-Girons, C. Plossu, G. Hollinger MRS 2010 spring meeting, april 5-9 (2010), San Francisco (USA)

# 56. Monolithic integration of III-V heterostructures on silicon using crystalline oxide buffers J. Cheng, G. Saint-Girons, P. Regreny, G. Patriarche, L. Largeau, M. Gendry and G. Hollinger MRS 2010 spring meeting, april 5-9 (2010), San Francisco (USA)

## 57. LaAlO<sub>3</sub>/Si capacitors: comparison of different molecular beam deposition processes and impact on electrical properties

S. Pelloquin, G. Saint-Girons, G. Grenet, N. Baboux, P. Regreny, D. Albertini, C. Plossu and G. Hollinger

MRS 2010 spring meeting, april 5-9 (2010), San Francisco (USA)

## 58. Nanoscale study of the influence of atomic oxygen on the electrical properties of LaAlO<sub>3</sub> thin high-k oxide films deposited by molecular beam epitaxy

W. Hourani, L. Militaru, B. Gautier, D. Albertini, A. Descamps-Mandine, S. Pelloquin, C. Plossu and G. Saint-Girons

MRS 2010 spring meeting, april 5-9 (2010), San Francisco (USA)

### 59. Defect free vertical NWs grown on SrTiO3 substrates by VLS-MBE

K. Naji, H. Dumont, G. Saint-Girons, G. Patriarche and M. Gendry MRS 2010 spring meeting, april 5-9 (2010), San Francisco (USA)

## 60. Epitaxy of BaTiO3 thin films on Si(001) using a SrTiO3 buffer layer for non-volatile memory application

G. Niu, Y. Shi, G. Saint-Girons, B. Gautier, P. Lecoeur, V. Pillard, G. Hollinger and B. Vilquin INFOS 2011 conference, june 21-24 (2011), Grenoble (France)

# 61. Monolithic integration of InP based heterostructures on silicon using SrTiO<sub>3</sub> templates A. Chettaoui, B. Gobaut, J. Penuelas, J. Cheng, G. Niu, L. Largeau, P. Regreny, G. Saint-Girons EuroMBE 2011 conference, March 20-23 (2011), L'Alpe d'Huez (France)

# 62. Early stages of the growth of InP and GaAs islands on SrTiO<sub>3</sub> substrates B. Gobaut, J. Penuelas, A. Chettaoui, J. Cheng, G. Grenet, L. Largeau and G. Saint-Girons EuroMBE 2011 conference, March 20-23 (2011), L'Alpe d'Huez (France)

## 63. Growth directions and structural properties of InP nanowires fabricated on Si and SrTiO<sub>3</sub> substrates

J. Penuelas, K. Naji, H. Dumont, G. Saint-Girons, G. Patriarche, M. Gendry EuroMBE 2011 conference, March 20-23 (2011), L'Alpe d'Huez (France)

64. Epitaxial growth of SrTiO<sub>3</sub> on Si: strain relaxation and formation of tetragonal domains G. Saint-Girons, G. Niu, J. Penuelas, L. Largeau, B. Vilquin, J.L. Maurice C. Botella and G. Hollinger

EuroMBE 2011 conference, March 20-23 (2011), L'Alpe d'Huez (France)

## 65. Crucial impact of oxygen vacancy defects on the ferroelectric characteristics of epitaxial BaTiO<sub>3</sub> thin films

G. Niu, B. Gautier, S. Yin, G. Saint-Girons, P. Lecoeur, V. Pillard, G. Hollinger, B. Vilquin E-MRS 2011 spring meeting, May 9-13 (2011), Nice (France).

## 66. Crucial impact of oxygen vacancy defects on the ferroelectric characteristics of epitaxial BaTiO<sub>3</sub> thin films

G. Niu, B. Gautier, S. Yin, G. Saint-Girons, P. Lecoeur, V. Pillard, G. Hollinger, B. Vilquin E-MRS 2011 spring meeting, May 9-13 (2011), Nice (France).

## 67. Orientation and strain of Ge nanodots on SrTiO<sub>3</sub> observed by Grazing Incidence X-ray Scattering

B. Gobaut, J. Penuelas, N. Blanc, V. Favre-Nicolin, G. Renaud and G. Saint-Girons Size and Strain VI, october 17-20 2011, Presqu'ile de Giens (France).

68. Epitaxial growth of SrTiO<sub>3</sub> on Si: strain relaxation and formation of tetragonal domains G. Saint-Girons, G. Niu, J. Penuelas, L. Largeau, B. Vilquin, J.L. Maurice C. Botella and G. Hollinger

Size and Strain VI, october 17-20 2011, Presqu'ile de Giens (France).

### 69. Direct epitaxy of III-V heterostructures on silicon using SrTiO<sub>3</sub>/Si templates

A. Chettaoui, B. Gobaut, J. Penuelas, J. Cheng, G. Niu, L. Largeau, P. Regreny and G. Saint-Girons

E-MRS 2012 spring meeting, May 14-18 (2012), Strasbourg (France).

## 70. Monolithic integration of Ge on SrTiO<sub>3</sub>: mismatch accommodation for very heterogeneous epitaxial systems

B. Gobaut, J. Penuelas, N. Blanc, V. Favre-Nicolin, G. Renaud, A. Danescu, J. Wang, I. Lefebvre, G. Saint-Girons

E-MRS 2012 spring meeting, May 14-18 (2012), Strasbourg (France).

## 71. Integration of ferromagnetic spinel oxide on silicon using structurally-compatible nanometric epitaxial buffer-layer

R. Bachelet, F. Sánchez, P. de Coux, B. Warot-Fonrose, V. Skumryev, G. Niu, B. Vilquin, G. Saint-Girons, G. Hollinger, J. Fontcuberta

E-MRS 2012 spring meeting, May 14-18 (2012), Strasbourg (France).

### 72. Ge/SrTiO<sub>3</sub> heterogeneous system

B. Gobaut, J. Penuelas, G. Grenet, D. Ferrah, A. Benamrouche, A. Chettaoui, Y. Robach, C. Botella, L. Largeau, M. El-Kazzi, M. G. Silly, F. Sirotti and G. Saint-Girons ECOSS conference 2012, Sept 3-7(2012), Edinburgh (UK)

## 73. Crystallography and physico-chemistry of the Ge/SrTiO<sub>3</sub> interface: how low adhesion energy affects mismatch accommodation and crystal orientation

G. Saint-Girons, B. Gobaut, A. Danescu, J. Penuelas, G. Grenet, N. Blanc, T. Zhou, V. Favre-Nicolin, G. Renaud, M. El-Kazzi, M. Silly and F. Sirotti

2012 MRS Fall Meeting, Nov. 25-30 (2012), Boston (USA)

## 74. Integration of ferromagnetic spinel oxides on silicon using ultrathin structurally-compatible epitaxial buffer-layers

R. Bachelet, F. Sánchez, P. de Coux, B. Warot-Fonrose, V. Skumryev, G. Niu, B. Vilquin, G. Saint-Girons, G. Hollinger, J. Fontcuberta

2012 MRS Fall Meeting, Nov. 25-30 (2012), Boston (USA)

### 75. Piezoelectric Pb(Zr,Ti)O<sub>3</sub> thin films on SrTiO<sub>3</sub>/GaAs

L. Louahadj, D. Le Bourdais, L. Largeau, G. Agnus, L. Mazet, R. Bachelet, P. Regreny, D. Albertini, V. Pillard, C. Dubourdieu, B. Gautier, P. Lecoeur, G. Saint-Girons E-MRS Fall meeting, sept 16-20 2013, Warsaw (Poland)

## 76. Integration of ferromagnetic spinel oxides on silicon using structurally-compatible epitaxial buffer-layers

R. Bachelet, L. Louahadj, G. Niu, C. Dubourdieu, G. Saint-Girons, P. de Coux, B. Warot-Fonrose, V. Skumryev, J. Fontcuberta, F. Sánchez

EMRS Spring meeting, may 27-31 2013, Strasbourg (France)

# 77. Molecular beam epitaxy for the growth of perovskite oxides on semiconductor platforms L. Louahadj, R. Bachelet, C. Dubourdieu, P. Regreny, C. Chaix, G.Saint-Girons EMRS Spring meeting, may 27-31 2013, Strasbourg (France)

### 78. Molecular beam epitaxy of functional oxides on silicon

L. Louahadj, R. Bachelet, P. Regreny, C. Chaix, G. Niu, G.Saint-Girons 17th EuroMBE conference, march 10-13 2013, Levi (Finland)

### 79. Weakly interacting epitaxial systems: the semiconductor/SrTiO<sub>3</sub> case

G. Saint-Girons, A. Danescu, B. Gobaut, J. Penuelas, G. Grenet, G. Renaud, N. Blanc, V. Favre-Nicollin, M. El-Kazzi, F. Sirotti, M. Silly

17th EuroMBE conference, march 10-13 2013, Levi (Finland)

## 80. Young modulus and Poisson ratio of polycristalline and single crystal PZT thin film measured by picosecond ultrasonics

F. Casset, A. Devos, J. Abergel, G. Le Rhun, B. Vilquin, R. Bachelet, G. Saint-Girons, P. Emery, P. Ancey, S. Fanget, E. Defaÿ

IEEE International ultrasonics symposium, july 21-25 2013, Prague (Czech Republic)

### 81. Molecular beam epitaxy of perovskite oxides on semiconductor platforms

L. Louahadj, R. Bachelet, C. Dubourdieu, N. Baboux, P. Regreny, C. Chaix, G.Saint-Girons Workshop on functional oxides, april 7-10 2013, Autrans (France)

### 82. Monolithic integration of functional oxides on GaAs

G. Agnus, P. Regreny, P. Lecoeur, L. Largeau, V. Pillard, L. Louahadj, R. Bachelet, N. Baboux, C. Dubourdieu and G. Saint-Girons

Workshop on functional oxides, april 7-10 2013, Autrans (France)

### 83. Weakly interacting epitaxial systems: the semiconductor/SrTiO3 case

A. Danescu, G. Saint-Girons, B. Gobaut, J. Penuelas, G. Grenet, G. Renaud, N. Blanc, V. Favre-Nicollin, M. El-Kazzi, F. Sirotti, M. Silly

Workshop on functional oxides, april 7-10 2013, Autrans (France)

### 84. Slot waveguide electro-optic modulator with ferroelectric oxide BaTiO3 on Silicon.

X. Hu, R. Orobtchouk, S. Cueff, P. R. Rojo Romeo, P. Regreny, R. Bachelet, L. Mazet, L. Louahadj, Ramah Moalla, C. Dubourdieu, B. Vilquin, G. Saint Girons, P. Castera, N. Sanchez, T. Angelova, A. Griol, A. M. Gutierrez, P. Sanchis

11th International Conference on Group IV Photonics, August 27-29 2014, Paris (France)

### 85. Electro-optic modulation with functional oxides monolithically integrated on silicon.

S. Cueff, X. Hu, R. Orobtchouk, P. Rojo-Romeo, R. Bachelet, B. Vilquin, M. Hayes, C. Dubourdieu, P. Regreny, G. Grenet, G. Saint-Girons, P. Castera, N. Sanchez, T. Angelova, L. Bellieres, A. Griol, F. López, A. M. Gutierrez, P. Sanchis

Silicon Photonics Summer School organized by PLAT4M project, june 29-july 4 2014, Ghent (Belgium)

### 86. Ferroelectric Pb Zr,Ti)O<sub>3</sub> thin layers on SrTiO<sub>3</sub>/GaAs

B. Meunier, L. Louahadj, D. Le Bourdais, L. Largeau, G. Agnus, L. Mazet, R. Bachelet, P. Regreny, D. Albertini, V. Pillard, C. Dubourdieu, B. Gautier, P. Lecoeur, G. Saint-Girons 26th IPRM conference, may 11-15 2014, Montpellier, (France)

### 87. Engineering of oxide based resistive switching for passive crossbar integration

F. Alibart, S. La Barbera, D. Vuillaume, M. Minvielle, G. Saint-Girons, R. Bachelet, C. Dubourdieu

EMRS 2014 spring meeting, may 26-30 2014, Lille (France)

## 88. Epitaxial growth of BaTiO<sub>3</sub> on semiconductor substrates by molecular beam epitaxy for ferroelectric devices

L. Mazet, R. Bachelet, L. Louahadj, C. Botella, M.M. Frank, J. Jordan-Sweet, I. Lauer, V. Narayanan, D. Albertini, B. Gautier, G. Saint-Girons, M. Hÿtch, S. Schamm-Chardon, C. Dubourdieu

EMRS 2014 Fall meeting, sept 15-18 2014, Warsaw (Poland)

## 89. Epitaxial growth of BaTiO<sub>3</sub> on Si and SOI by molecular beam epitaxy for ferroelectric applications

L. Mazet, R. Bachelet, L. Louahadj, S. Schamm-Chardon, M. Hytch, D. Albertini, B. Gautier, G. Saint-Girons, C. Dubourdieu

ISAF 2014, May 12-16, 2014, Penn State University, PA, (USA)

# 90. Ferroelectric BaTiO<sub>3</sub> thin films grown on Si(001) by molecular beam epitaxy L. Mazet, R. Bachelet, L. Louahadj, R. Moalla, D. Albertini, B. Gautier, G. Saint-Girons, C. Dubourdieu

European Conference on Application of Polar Dielectrics (ECAPD), July 7-11, 2014, Vilnius, (Lithuania)

### 91. Epitaxial pyroelectric thin films on silicon for thermal energy harvesting

R. Moalla, L. Mazet, L. Louahadj, Q. Liu, J. Penuelas, B. Vilquin, G. Saint-Girons, C. Dubourdieu, R. Bachelet

E-MRS 2014 Spring Meeting, may 26-30 2014, Lille, (France)

### 92. Epitaxial pyroelectric thin films on silicon for thermal energy harvesting

R. Moalla, L. Mazet, L. Louahadj, Q. Liu, J. Penuelas, B. Vilquin, G. Saint-Girons, C. Dubourdieu, R. Bachelet

Nanotech MEET conference 2014, April 24-26, 2014, Hammamet, (Tunisa)

### 93. Local tetragonality of epitaxial BaTiO<sub>3</sub> thin films on Si for ferroelectric applications

S. Schamm-Chardon, T. Denneulin, M. Hÿtch, L. Mazet, R. Bachelet, G. Saint-Girons, C. Dubourdieu

18th international Microscopy congress, Sept 7-12 2014, Prag. (Czech Republic)

### 94. Epitaxial Growth of Ferroelectric Pb(Zr,Ti)O<sub>3</sub> Layers on GaAs

B. Meunier, L. Louahadj, D. Le Bourdais, L. Largeau, G. Agnus, L. Mazet, R. Bachelet, P. Regreny, C. Botella, G. Grenet, D. Albertini, V. Pillard, C. Dubourdieu, B. Gautier, P. Lecoeur, G. Saint-Girons

MRS 2014 Spring meeting, april 21-25 2014, San Francisco, (USA)

### 95. Ir / SrTiO<sub>3</sub> / Si multilayers: a promising substrate for diamond heteroepitaxy

K.H. Lee, S. Saada, J.C. Arnault, G. Saint-Girons, R. Bachelet, A. Tallaire, J. Achard, H. Bensalah, I. Stenger, J. Barjon

DCM 2015 conference, 6-10 septembre 2015, Band Homburg, (Germany).

## 96. Epitaxial growth of ferroelectric Pb(Zr,Ti)O<sub>3</sub> thin layers on SrTiO3-templated GaAs/InGaAs quantum well structure for opto-mechanical application

B. Meunier, R. Bachelet, B. Vilquin, P. Rojo-Romeo, G. Grenet, C. Botella, P. Regreny, J. Penuelas, G. Agnus, P. Lecoeur, V. Pillard, N. Chauvin, L. Largeau and G. Saint-Girons EMRS 2015 Spring Meeting, 11-15 mai 2015, Lille, (France).

### 97. Soft chemistry integration of ferromagnetic La<sub>0.7</sub>Sr<sub>0.3</sub>MnO<sub>3</sub> on silicon

José M. Vila-Fungueiriño, A. Carretero-Genevrier, B. Rivas-Murias, R. Moalla, R. Bachelet, G.Saint-Girons, F. Rivadulla

EMRS 2015 Spring Meeting, 11-15 mai 2015, Lille, (France).

## 98. Thermal energy harvesting through epitaxial pyroelectric oxide films integrated on silicon

R. Moalla, Q. Liu, José M. Vila-Fungueiriño, A. Carretero-Genevrier, B. Rivas-Murias, F. Rivadulla, G. Saint-Girons, B. Vilquin, N. Baboux, G. Sebald, C. Dubourdieu, R. Bachelet EMRS 2015 Spring Meeting, 11-15 mai 2015, Lille, (France).

99. Epitaxial pyroelectric  $Pb(Zr,Ti)O_3$  thin films on silicon for thermal energy harvesting R. Moalla, L. Liu, G. Saint-Girons B. Vilquin, N. Baboux, G. Sebald, C. Dubourdieu, R. Bachelet

EMRS 2015 Spring Meeting, 11-15 mai 2015, Lille, (France).

## 100. Epitaxial growth of ferroelectric Pb(Zr,Ti)O<sub>3</sub> thin layers on SrTiO<sub>3</sub>-templated GaAs/InGaAs quantum well structure for opto-mechanical application

B. Meunier, R. Bachelet, B. Vilquin, P. Rojo-Romeo, G. Grenet, C. Botella, P. Regreny, J. Penuelas, G. Agnus, P. Lecoeur, V. Pillard, N. Chauvin, L. Largeau and G. Saint-Girons EuroMBE 2015 conference, 15-18 mars 2015, Canazei, (Italie).

### 101. Strong electrocaloric anisotropy in epitaxial Pb(Zr,Ti)O<sub>3</sub> heterostructures

R. Moalla, B. Vilquin, G. Saint-Girons, N. Baboux, G. Sebald, R. Bachelet EMRS 2015 Fall Meeting, 15-18 septembre 2015, Varsovie, (Pologne).

## 102. Monolithic integration of pyroelectric oxide films on silicon for thermal energy harvesting and cooling applications

R. Moalla, N. Baboux, G. Sebald, B. Vilquin, G. Saint-Girons, R. Bachelet EMRS 2015 Fall Meeting, 15-18 septembre 2015, Varsovie, (Pologne).

## 103. Electromechanical response of amorphous LaAlO3 thin film probed by scanning probe microscopies

A. Borowiak, H. Tanaka, N. Baboux, D. Albertini, B. Vilquin, G. Saint-Girons B. Gautier ISAF 2015 conference, 24-27 mai 2015, Singapore.

### 104. Monolithic integration of functional oxides in silicon by chemical solution deposition

A. Carretero-Genevrier, M. Gich, J. M. Vila-Fungueiriño, G. L. Drisko, L. Picas, J. Gazquez, B. Rivas-Murias, R. Bachelet, G.Saint-Girons, J. Rodriguez-Carvajal, F. Rivadulla, C. Sanchez MRS 2015 Spring Meeting, 6-10 avril 2015, San-Francisco (USA).

## 105. Chemical solution deposition to epitaxial functional complex oxide nanostructures and thin films

A. Carretero-Genevrier, M. Gich, R. Bachelet, G. Saint-Girons, J.M. Vila-Fungueiriño, B. Rivas-Murias, J. Gazquez, G.L. Drisko, Judith Oró-Solé, E. Ferain, T. Puig, X. Obradors, F. Rivadulla, J. Rodriguez-Carvajal, C. Sanchez, N. Mestres

MRS 2015 Spring Meeting, 6-10 avril 2015, San-Francisco (USA).

### 106. Functional spinel oxide heterostructures on silicon

R. Bachelet, P. de Coux, B. Warot-Fonrose, V. Skumryev, G. Niu, B. Vilquin, G. Saint-Girons, F. Sánchez

MRS 2015 Spring Meeting, 6-10 avril 2015, San-Francisco (USA).

### 107. Hybrid silicon-ferroelectric oxide slot waveguide for on-chip optoelectronics

S. Cueff, R. Orobtchouk, P. Rojo-Romeo, X. Hu, R. Bachelet, P. Regreny, B. Vilquin and G. Saint-Girons

MRS 2015 Fall Meeting, 29 novembre – 4 décembre 2015, Boston (USA).

## 108. Structural study of BaTiO<sub>3</sub> films grown on Si<sub>1-x</sub>Ge<sub>x</sub> substrates by molecular beam epitaxy: role of passivation

L. Mazet, C. Botella, R. Cours, R. Bachelet, G. Saint-Girons, M.M. Frank, V. Narayanan, S. Schamm-Chardon, C. Dubourdieu

MRS 2015 Fall Meeting, 29 novembre – 4 décembre 2015, Boston (USA).

### 109. Strain and Cation Stoichiometry in Epitaxial BaTiO<sub>3</sub> Thin Films Grown on Silicon

S. Schamm-Chardon, C. Magen, R. Guzman, L. Mazet, R. Cours, R. Bachelet, G. Saint-Girons, M. Hytch, C. Dubourdieu

MRS 2015 Fall Meeting, 29 novembre – 4 décembre 2015, Boston (USA).

### 110 Functional oxide pressure sensor

D. Le Bourdais, G. Agnus, T. Maroutian, V. Pillard, G. Saint-Girons, B. Vilquin, E. Lefeuvre, P. Lecoeur,

EMRS Spring Meeting, May 11-15, 2015.Lille (France

## 111. Interface reactivity and epitaxial growth of SrTiO3 and other functional oxides on Si and GaAs

B. Meunier, R. Moalla, A. Carretero-Genevrier, L. Largeau J. Gazquez, P. Regreny, C. Botella, J. Penuelas, B. Vilquin, B. Wague, G. Grenet, G. Agnus, P. Lecoeur, M.G. Silly, F. Sirotti, R. Bachelet and G. Saint-Girons

IC-MBE 2016 international conference, 4-9 sept 2016, Montpellier (France)

### 112. GaAs Core / SrTiO<sub>3</sub> Shell Nanowires Grown by Molecular Beam Epitaxy

X. Guan, J. Becdelievre, B. Meunier, A. Benali, G. Saint-Girons, R. Bachelet, P. Regreny, C. Botella, G. Grenet, N. P. Blanchard, X. Jaurand, M. G. Silly, F. Sirotti, N. Chauvin, M. Gendry, J. Penuelas

IC-MBE 2016 international conference, 4-9 sept 2016, Montpellier (France)

### 113. GaAs nanowires with oxidation-proof arsenic capping for the growth of heteroepitaxial shell

X. Guan, J. Becdelievre, A. Benali, C. Botella, G. Grenet, P. Regreny, N. Chauvin, N. P. Blanchard, X. Jaurand, G. Saint-Girons, M. Gendry, J. Penuelas IC-MBE 2016 international conference, 4-9 sept 2016, Montpellier (France)

### 114. LiNbO<sub>3</sub> Films for Acoustic Wave Applications

A. Bartasyte, S. Oliveri, T. Baron, R. Salut, S. Margueron, S. Ballandras, G. Saint-Girons, B. Gautier, R. Bachelet, D. Albertini, P. Boulet

IEEE International Ultrasonics Symposium, 18-21 sept 2016, Tours (France)

### 115. Effect of Bias Enhanced Nucleation parameters on diamond heteroepitaxy on *Ir/SrTiO*<sub>3</sub>/Si (001)

K.H. Lee, S. Saada, J.C. Arnault, G. Saint-Girons, R. Bachelet MRS Spring meeting 2016, March 28<sup>th</sup> – April 1<sup>st</sup> 2016, Phoenix (USA)

### 116. Functional oxides on silicon for on-chip thermal management

R. Moalla, M. Apreutesei, B. Vilquin, P. Regreny, C. Botella, G. Grenet, A. Carretero-Genevrier, J. Gazquez, G. Sebald, N. Baboux, R. Debord, S. Pailhès, G. Saint-Girons, R. Bachelet

XV<sup>th</sup> Electroceramics conference, 27-29 june 2016, Limoges (France)

### 117. (001) Ir / SrTiO<sub>3</sub> / Si: a promising substrate for diamond heteroepitaxy

K. H. Lee, S. Saada, N. Tranchant, J.C. Arnault, R. Moalla, G. Saint-Girons, R. Bachelet, A. Tallaire, O. Brinza, J. Achard, H. Bensalah, I. Stenger, J. Barjon SBDD XXI conference, 9-11 march 2016, Hasselt (Belgium)

### 118. Ferroelectric oxide slot waveguide electro-optic modulator on Silicon

S. Cueff, R. Orobtchouk, P. Rojo-Romeo, A. M. Gutierrez, P. Castera, Á. Rosa, B. Wague, X. Hu, R. Bachelet, P. Regreny, B. Vilquin, P. Sanchis and G. Saint-Girons SPIE Photonic West 2016 Conference, 13-18 february 2016, San-Francisco (USA)

### 119. Diamond heteroepitaxy on Ir / SrTiO3 / Si (001) substrates: from nucleation to thick films characterizations

K. H. Lee, S. Saada, N. Tranchant, J.C. Arnault, R. Moalla, G. Saint-Girons, R. Bachelet, A. Tallaire, O. Brinza, J. Achard, H. Bensalah, I. Stenger, J. Barjon, C. Ricolleau 28th international conference on diamond and related materials, 3-7 september 2017, Gothenborg (Sweden)

### 120. Epitaxial growth of nanostructured functional oxides on silicon by solution chemistry

J.M. Vila-Fungueiriño, A. Gómez, R. Moalla, G. Saint-Girons, C. Magen, J. Gázquez, R. Bachelet, M. Gich, F. Rivadulla, A. Carretero-Genevrier EMRS 2017 Spring meeting, 22-26 may 2017, Strasbourg (France)

### 121. Perovskite oxide engineering by molecular beam epitaxy for integrated thermoelectricity M. Bouras, M. Apreutesei, R. Moalla, R. Debord, P. Regreny, C. Botella, G. Grenet, M. Bugnet, A. Carretero-Genevrier, J. Gazquez, Q. d'Acremont, S. Dilhaire, P.O. Chapuis, S. Pailhès, G. Saint-Girons, R. Bachelet

ECT 2017 conference, 25-27 september 2017, Padua (Italy)

### 122. Perovskite oxide engineering using molecular beam epitaxy

M. Bourras, M. Apreutesei, N. Baboux, S. Cueff, R. Debord, N. Chauvin, S. Pailhès, R. Bachelet, G. Saint-Girons

EMRS 2017 Fall meeting, 18-21 september 2017, Warsaw (Poland)

# 123. Ultra-long self-catalyzed GaAs nanowires grown by Molecular Beam Epitaxy on Si(111) J. Becdelievre, X. Guan, N. Chauvin, P. Regreny, M. Gendry, G. Patriarche, G. Saint-Girons, B. Gautier, J. Penuelas

Nanowire week 2017, may 28 – june 2 2017, Lund (Sweden)

## 124. Decreasing thermal conductivity by atomic engineering in epitaxial oxide films for enhanced integrated thermoelectricity

D. Han, M. Bouras, R. Moalla, M. Apreutesei, R. Debord, P. Regreny, C. Botella, G. Grenet, J. Gazquez, M. Bugnet, Q. d'Acremont, S. Dilhaire, P.O. Chapuis, S. Pailhès, G. Saint-Girons, R. Bachelet

CNRS GDRe thermal nanosciences and nanoengineering conference, October 11-12 2018, Lyon (France)

### 125. Lateral diamond Schottky diodes on heteroepitaxial substrate

J. Letellier, E. Gheeraert, D. Eon, G. Saint-Girons, R. Bachelet, L. Mehmel, R. Issaoui, A. Tallaire, J. Achard, I. Stenger, J. Barjon, K. H. Lee, J. Delchevalrie, N. Tranchant, S. Saada, J. C. Arnault

SBDD XXIII Hasselt Diamond Workshop, march 7-9 2018, Hasselt (Belgium)

## 126. Nanoscale insights into the synthesis of GaAs core / shell nanowires for water splitting applications through in situ heating in the TEM

L. Fouquat, X. Guan, C. Chevalier, G. Saint-Girons, G. Grenet, J. Penuelas, and M. Bugnet 19th International Microscopy Congress, Sept. 9-14 2018, Sydney (Australia)

## 127. Chemical integration of functional oxide nanostructured thin films on silicon with excellent physical properties

J. M. Vila-Fungueiriño, R. Bachelet, G. Saint-Girons, C. Magen, A. Gomez, J. Gazquez, N. Mestres, F. Rivadulla, M. Gich, A. Carretero-Genevrier

EMRS 2018 Spring meeting, 18-22 june 2018, Strasbourg (France)

### 128. Thermoelectric perovskite-oxide epitaxial films grown by MBE

D. Han, M. Bouras, R. Moalla, C. Botella, A. Benamrouche, G. Grenet, B. Canut, R. Debord, V. Giordano, S. Pailhès, G. Saint-Girons, R. Bachelet EMRS 2019 Spring meeting, 27-31 may 2019, Nice (France)

### 129. P-type thermoelectric LaCrO<sub>3</sub>-based epitaxial thin films grown by MBE

D. Han, M. Bouras, C. Botella, A. Benamrouche, G. Saint-Girons, R. Bachelet EMRS 2019 Spring meeting, 27-31 may 2019, Nice (France)

## 130. Perovskite oxide based hyperbolic epitaxial superlattices grown by oxide molecular beam epitaxy

M. Bouras, D. Han, S. Cueff, R. Bachelet, G. Saint-Girons EuroMBE 2019, 17-20 february 2019, Lenggries (Germany)

## 131. Nucleation of heteroepitaxial diamond films: toward in situ characterization of domain formation

J. Delchevalrie, G. Saint-Girons, R. Bachelet, S. Saada, J. C. Arnault ICDCM 2019 conference, 8-12 september 2019, Seville (spain)

### 132. Epitaxial 33°Y-oriented LiNbO3 films for Silicon Technology

A. Bartasyte, S. Oliveri, S. Margueron, R. Bachelet, G. Saint-Girons, D. Albertini, B. Gautier, A. Borzi, F. Pierre, M. Bousquet, A. Reinhardt, P. Boulet, E. Blanquet Joint IEEE ISAF-EMF-ICE-IWPM-PFM meeting, 14-19 july 2019, Lausanne (Switzerland)

## 133. Integration of Li<sub>4</sub>Ti<sub>5</sub>O<sub>12</sub> Thin Films on Silicon for Intercalation-based Solid State Devices

S.D. Lacey, E. Gilardi, C. Merckling, G. Saint-Girons C. Botella, D. Pergolesi & M. El Kazzi EMRS 2020 Spring meeting, *cancelled* 

### 134. Coherent orientation of size-selected FeRh clusters deposited on crystalline BaTiO<sub>3</sub>

A. Reyes-Contreras, V. Dupuis, D. Le-Roy, L. Bardotti, A. Tamion, G. Saint-Girons, R. Bachelet, I. C. Infante, G. Renaud, A. Resta, L. E. Díaz-Sánchez and F. Tournus Cluster meeting 2021, May 19-14 2021, Prague (Tchec Republic)

### 135. Ferroelectric Properties Dependence on Thickness in Epitaxial La-Doped HfO<sub>2</sub> Films

T. Song, R. Bachelet, G. Saint-Girons, I. Fina, F. Sánchez

EMRS Fall 2021, September 20-23 2021, virtual

### 136. Enhanced Ferroelectric Properties of Epitaxial La-Doped Hf0.5Zr0.5O2 Thin Films

T. Song, R. Bachelet, G. Saint-Girons, R. Solanas, I. Fina, F. Sánchez ISAF-ISIF-PFM 2021, May 16-21 2021, virtual

## 137. Integration of Li<sub>4</sub>Ti<sub>5</sub>O<sub>12</sub> Thin Films on Silicon towards High-Rate Performance Microbatteries

S.D. Lacey, E. Gilardi, E. Müller, C. Merckling, G. Saint-Girons, C. Botella, R. Bachelet, D. Pergolesi, M. El Kazzi

Swiss Battery Days 2021, February 15-17 2021, virtual

## 138. Sb<sub>2</sub>S<sub>3</sub> thin film for tunable nanophotonic devices: phase switching mechanisms and thin film characterization

C. Laprais, L. Berguiga, N. Baboux, B. Fornacciari, C. Botella, A. Moreau, J. Lumeau, G. Saint Girons and S. Cueff

META 2022 conference, July 19-22 2022, Torremolinos, (Spain)

## 139. Giant thermoelectric tuning by epitaxial strain of p-type Sr-doped LaCrO<sub>3</sub> transparent thin films

D. Han, R. Moalla, I. Fina, V.M. Giordano, M. d'Esperonnat, C. Botella, G. Grenet, R. Debord, S. Pailhès, G. Saint-Girons R. Bachelet

EMRS 2022 Spring Meeting, May 30 – June 3 2022, virtual

### 140. Towards p-type MBE-grown SrTi<sub>1-x</sub>Al<sub>x</sub>O<sub>3</sub> films for thermoelectric applications

M. d'Esperonnat, C. Adessi, C. Botella, A. Lamirand, B. Canut, G. Saint-Girons, R. Bachelet EMRS 2022 Spring Meeting, May 30 – June 3 2022, virtual

### 141. Ferroelectric La-Doped HfO2 Epitaxial Thin Films

T. Song, H. Tan, R. Bachelet, G. Saint-Girons, N. Dix, I. Fina, F. Sánchez ISAF 2022 conference, June 27 – July 1 2022, Tours (France)

### 142. Optical switch of Sb<sub>2</sub>S<sub>3</sub> phase change material for tunable nanophotonic applications

C. Laprais, L. Berguiga, G. Saint Girons, N., S. Cueff

EMRS 2023 Spring meeting, May 29 – June 2 2023, Strasbourg (France)

### 143. Reversible optical switch of Sb<sub>2</sub>S<sub>3</sub> thin films for tunable nanophotonic applications

C. Laprais, L. Berguiga, N. Baboux, G. Saint-Girons, S. Cueff

MRS 2023 Spring meeting, April 10-14 2023, San Francisco (USA)

### 144. Optical switch of Sb<sub>2</sub>S<sub>3</sub> for tunable nanophotonics

C. Laprais, L. Berguiga, C. Zruonba, J. Bouvier, N. Baboux, G. Saint-Girons, S. Cueff E\PCOS 2023, September 17-20 2023, Roma (Italy)

### 145. Reconfigurable SiGe waveguide using Sb<sub>2</sub>S<sub>3</sub> phase-change material in the mid-IR

A. Biegański, M. Perestjuk, R. Armand, A. Della Torre, C. Laprais, G. Saint-Girons, V. Reboud, J.M. Hartmann, J.H. Tortai, A. Moreau, J. Lumeau, A. Mitchell, T. Nguyen, C. Monat, S. Cueff and C. Grillet

CLEO 2024, may 5-10 2024, Charlotte (USA)

### 146. Laser Induced Reversible Phase Transition of Sb<sub>2</sub>S<sub>3</sub> for Tunable Nanophotonics

C. Laprais, L. Berguiga, C. Zrounba, J. Bouvier, N. Baboux, G. Saint-Girons, S. Cueff CLEO 2024, may 5-10 2024, Charlotte (USA)

### 147. Absorption profile of a MBE atomic beam measured with TDLAS

R. Rousseau, J. Morville, C. Botella, G. Saint-Girons

FLAIR 2024, september 16-20 2024, Assisi (Italy)

## 148. Electrical switch of phase change materials: toward the control of crystallinity for multi-level reconfigurable nanophotonics

C. Laprais, N. Baboux, L. Berguiga, G. Saint-Girons and S. Cueff

SPIE Optics and Photonics 2024, August 18-22 2024, San Diego (USA)

## 149. Giant tuning of transport properties and orbital switching by epitaxial strain in Sr-doped LaCrO<sub>3</sub> thin films

C D. Han, A.D. Lamirand, C. Furgeaud, C. Botella, G. Saint-Girons, I. Fina, V.M. Giordano, R. Debord, S. Pailhès, Y. Joly, P. Schoeffmann, P. Ohresser, R. Bachelet

iWOE30 conference, September 29 – October 2 2024, Darmstadt (Deustchland)

## 150. Continuum-source cavity-enhanced optical flux monitoring to control thin layer deposition processes

R. Rousseau, C. Botella, J. Morville, L. Berguiga, M. Bounab, C. Furgeaud, R. Bachelet and G. Saint-Girons

CSW 2024 conference, June 3-6 2024, Lund (Sweden)

### 151. Programmable Multilevel Nanophotonics with Chalcogenide Phase-Change Materials

F. Bentata, C. Laprais, L. Berguiga, N. Baboux, G. Saint-Girons, X. Letartre and S. Cueff SPIE Photonics West 2024 conference, January 27-February 02 2024, San Francisco (USA)

## 152. Electrical switch of phase change materials: toward the control of crystallinity for multi-level reconfigurable nanophotonics

C. Laprais, N. Baboux, L. Berguiga, G. Saint Girons, and S. Cueff SPIE Optics and Photonics 2024, August 18-22 2024, San Diego (USA)

### 153. LaCoO<sub>3</sub> epitaxial thin films for advanced thermoelectric applications

T. Zhu, A.D. Lamirand, C. Furgeaud, C. Botella, A. Benamrouche, B. Fornacciari, B. Canut, P. Regreny, G. Saint-Girons, R. Bachelet

EMRS conference, may 26-30 2025, Strasbourg (France) prix meilleur poster

## 154. Nanoimprint lithography of low-loss phase-change materials: Towards large-scale reconfigurable nanophotonics

F. Bentata, M. Mraouni, C. Chevalier, L. Berguiga, X. Letartre, T.T. Nguyen, C. Laprais, N. Baboux, G. Saint-Girons, H.S. Nguyen, S. Monfray, P. Genevet, S. Cueff E\PCOS conference, September 23-26 2025, Marseille (France)

### 155. Epitaxial growth of LaCoO3 thin films by MBE

T. Zhu, A. D. Lamirand, C. Furgeaud, C. Botella, A. Benamrouche, P. Regreny, G. Saint-Girons, R. Bachelet

EuroMBE conference, march 9-13 2025, Auron (France)

### 156. Strong optical anisotropy in epitaxial SrO(SrTiO3)n Ruddlesden-Popper thin layers M. Boyrosh, C. Eurgeand, S. Chaff, L. Borgania, B. Boshelet, M. Boyros, L. Lorgany, C. Sain

M. Bounab, C. Furgeaud, S. Cueff, L. Berguiga, R. Bachelet, M. Bouras, L. Largeau, G. Saint-Girons

EuroMBE conference, march 9-13 2025, Auron (France)

### 157. Towards p-type thermoelectric LaCoO3-based epitaxial thin films

T. Zhu, A. D. Lamirand, C. Furgeaud, C. Botella, A. Benamrouche, B. Fornacciari, B. Canut, P. Regreny, G. Saint-Girons, S. Pailhès, R. Bachelet

ECT25 conference, September 8-12 2025, Nancy (France)

## <u>Interventions dans des conférences/workshops nationaux/sans actes</u>

## 1. Epitaxie en Phase Vapeur aux Organo-Métalliques et caractérisation de boîtes quantiques InAs/GaAs pour les applications laser à 1,3 µm

G. Saint-Girons, G. Patriarche, L. Largeau, J. Coelho, A. Mereuta, J.M. Gérard, I. Sagnes COLOQ7 Rennes (2001)

### 2. Laser 1.55 µm à émission par la surface accordable en longueur d'onde

J.L. Leclerq, P. Régrény, P. Viktorovitch, I. Sagnes, G. Saint-Girons, C. Mériadec, A. Mereuta, A. Plais, J. Jacquet

Journées Nationales de la Micro et de l'Optoélectronique, Aussois, 2001.

3. Boîtes quantiques d' In(Ga)As sur GaAs par EPVOM – Etude de la formation des îlots Y. Chriqui, G. Saint-Girons, G. Patriarche, J-M. Moison, et I. Sagnes Action Spécifique Boîtes Quantiques, Rennes (France), Mai 2002

## 4. Croissance de boîtes quantiques d'In(Ga)As/GaAs par EPVOM sur pseudo-substrat de Ge/Si (100) pour la réalisation de composants émettant à 1,3 µm

Y. Chriqui, G. Saint-Girons, G. Patriarche, J-M. Moison, S. Bouchoule, I. Sagnes, O. Kermarrec, Y. Campidelli, et D. Bensahel

Journées Nationales de Micro et Optoélectronique (JNMO), Saint-Aygulf (France), 29 Septembre-2 Octobre 2002

## 5. Emission laser continue à 1.5µm d'un VCSEL en cavité externe pompé optiquement réalisé par EPVOM en une seule étape d'épitaxie

C. Symonds, I. Sagnes, A. Garnache, S. Hoogland, G. Saint-Girons, A.C. Tropper and J.-L. Oudar

Journées Nationales de Micro et Optoélectronique (JNMO), Saint-Aygulf (France), 29 Septembre-2 Octobre 2002.

## 6. Photodétection proche infrarouge et électromodulation de l'absorption interbande et intrabande avec des boîtes quantiques auto-assemblées Ge/Si

P. Boucaud, M. El kurdi, S. Sauvage, G. Fishman, O. Kermarrec, Y. Campidelli, D. Bensahel, G. Saint-Girons, G. Patriarche, I. Sagnes

Journées Nationales de Micro et Optoélectronique (JNMO), Saint-Aygulf (France), 29 Septembre-2 Octobre 2002

### 7. Etudes optiques de laser accordable à base de microcavité opto mécanique

A. Bakouboula, T. Benyattou, J.L. Leclercq, O. Regreny, P. Viktorovitch, I. Sagnes, G. Saint-Girons, S. Bouchoule, A. Plais, J. Jacquet

Journées Nationales de Micro et Optoélectronique (JNMO), Saint-Aygulf (France), 29 Septembre-2 Octobre 2002

## 8. Boîtes quantiques d'In(Ga)As/GaAs épitaxiées par EPVOM pour l'émission à 1,3 µm : croissance et lasers

G. Saint-Girons et I. Sagnes

Action Spécifique STIC « Boîtes Quantiques pour télécommunications optiques », 24 Mai 2002 à Rennes.

### 9. Boîtes quantiques Ge/Si pour télécommunications optiques

P. Boucaud, M. El kurdi, S. Sauvage, G. Fishman, V. Le Thanh, D. Bouchier, O. Kermarrec, Y. Campidelli, D. Bensahel, G. Saint-Girons, G. Patriarche, I. Sagnes

Communication invitée, Action spécifique STIC "Boîtes quantiques pour télécommunications optiques", Rennes 24 Mai 2002.

## 10. Photodétection et électromodulation proche infrarouge avec des îlots auto-assemblés Ge/Si insérés dans des guides d'onde SiGe et silicium sur isolant

M. El kurdi, P. Boucaud, S. Sauvage, G. Fishman, O. Kermarrec, Y. Campidelli, D. Bensahel, G. Saint-Girons, G. Patriarche, I. Sagnes

Journées IV-IV – grenoble 13-15 Janvier 2003.

## 11. Boîtes quantiques d'InGaAs/GaAs épitaxiées par EPVOM : pour l'émission à 1,3 µm : propriétés structurales et optiques et étude de lasers à émission par la tranche

G. Saint-Girons, G. Patriarche et I. Sagnes,

Journées IV-IV – grenoble 13-15 Janvier 2003.

## 12. Photodétection et électromodulation proche infrarouge avec des îlots auto-assemblés Ge/Si insérés dans des guides d'onde SiGe et silicium sur isolant

M. El kurdi, P. Boucaud, S. Sauvage, G. Fishman, O. Kermarrec, Y. Campidelli, D. Bensahel, G. Saint-Girons, G. Patriarche, I. Sagnes

Journée Boîtes quantiques 2003, LPN marcoussis 26 Juin 2003

## 13. Croissance de boîtes quantiques d'In(Ga)As/GaAs par EPVOM sur pseudo-substrat de Ge/Si (100) pour la réalisation de composants émettant à 1,3 µm

Sagnes, D. Bensahel, S. Bouchoule, Y. Campidelli, Y. Chriqui, O. Kermarrec, J-M. Moison, G. Patriarche, G. Saint-Girons

4èmes Journées "Hétérostructures à semiconducteurs IV-IV", 1ères Journées "Composants Micro et Nano-électroniques", Grenoble (France), Janvier 2003

## 14. Etude de la croissance par EPVOM et des propriétés optiques de boîtes quantiques d'In(Ga)As/GaAs sur pseudo-substrat de Ge/Si (100) non désorienté

Y. Chriqui, G. Saint-Girons, G. Patriarche, J-M. Moison, S. Bouchoule, I. Sagnes, O. Kermarrec, Y. Campidelli, et D. Bensahel

Journées Nationales du Réseau Doctoral de Microélectronique (JNRDM), Toulouse (France), 13-18 mai 2003

## 15. Optimisation du GaAs pour la croissance par EPVOM de boîtes quantiques d'In(Ga)As/GaAs pour l'émission à 1,3µm sur Ge/Si (100)

Y. Chriqui, G. Saint-Girons, G. Patriarche, J-M. Moison, I. Sagnes, O. Kermarrec, Y. Campidelli, et D. Bensahel,

Journée Nationale des Boîtes Quantiques, Marcoussis (France), 26 Juin 2003

## 16. Optimisation du GaAs pour la croissance par EPVOM de boîtes quantiques d'In(Ga)As/GaAs pour l'émission à 1,3µm sur Ge/Si (100)

Y. Chriqui, G. Saint-Girons, G. Patriarche, J-M. Moison, I. Sagnes, O. Kermarrec, Y. Campidelli, et D. Bensahel

Congrès de la Société Française de Physique, Lyon (France), 7-10 Juillet 2003

### 17. Vers l'organisation d'îlots In(Ga)As grâce à un réseau de dislocations sous-jacentJ.

Coelho, G. Patriarche, C. Mériadec, C. David, I. Sagnes, G. Saint-Girons, A. Lemaître, L. Largeau, F. Glas.

Congrès de la Société Française de Physique, Lyon (France), 7-10 Juillet 2003

## 18. Réduction de la durée de vie des porteurs dans un puits quantique près de la surface C. Symonds, J. Mangeney, I. Sagnes, G. Saint-Girons, K. Meunier et S. Bouchoule

Journées nationales de la micro-optoélectronique, 8-11 juin 2004, La Grande Motte (France)

## 19. Boîtes quantiques InAs/InP(001) émettant à 1.55 µm obtenues par épitaxie en phase vapeur aux organométalliques

A. Michon, G. Patriarche, I. Sagnes, G. Beaudoin and G. Saint-Girons Journées « Matériaux Semiconducteurs pour Nanostructures » (GDR Nanoélectronique), Lille, 13-14 octobre 2005.

## 20. Boîtes quantiques InAs/InP(001) émettant à 1,55 $\mu m$ réalisées par epitaxie en phase vapeur aux organométalliques

A. Michon, G. Patriarche, G. Beaudoin, Isabelle Sagnes, G. Saint-Girons Journées Nationales de l'Optique Guidée, 8-10 novembre 2005, Chambéry

## 21. Croissance de nenostructures de Si, Ge et de III-V sur oxydes monocristallins pour l'intégration monolithique de nouvelles fonctions sur silicium

L. Arzel, M. Gendry, B. Gautier, G. Saint-Girons et G. Hollinger Journées Nanosciences Rhône-Alpes, novembre 2005, Lyon

## 22. Imagerie des propriétés électroniques de boîtes quantiques InAs/InP(001) par microscopie à force atomique avec pointe conductrice

K. Smaali, M. Troyon, A. El Hdiy, M. Molinari, G. Saint-Girons, G. Patriarche, A. Michon, G. Beaudoin, I. Sagnes

Journées nationales de la micro-optoélectronique, 4-7 avril 2006, Aussois (France)

### 23. Boîtes et fils quantiques InAs/InP(001) émettant à 1,55 µm fabriqués par EPVOM

A. Michon, I. Sagnes, G. Patriarche, Grégoire Beaudoin and G. Saint-Girons Journées nationales de la micro-optoélectronique, 4-7 avril 2006, Aussois (France)

## 24. Spectroscopie de boîtes quantiques uniques d'InAs/InP(001) réalisées par EPVOM à 1.55 µm

N. Chauvin, G. Brémond, C. Bru-Chevallier, G. Saint-Girons, A. Michon, G. Patriarche, G. Beaudoin, I. Sagnes

Journées nationales de la micro-optoélectronique, 4-7 avril 2006, Aussois (France)

### 25. Epitaxial growth of LaAlO3 on Si(001) using interface engineering

C. Merckling, G. Delhaye, M. El-Kazzi, S. Gaillard, Y. Rozier, L. Rapenne, B. Chenevier, O. Marty, G. Saint-Girons, M. Gendry, Y. Robach, G. Hollinger 14<sup>th</sup> workshop on dielectrics in microelectronics, 26 to 28 june 2006, Catania (Italy)

### 26. Boîtes et fils quantiques InAs/InP(001) émettant à 1,55 µm fabriqués par EPVOM

A Michon, I. Sagnes, G. Patriarche, G. Beaudoin, et G. Saint-Girons

10<sup>èmes</sup> journées de la matière condensée (JMC10), August 28 to September 2 2006, Toulouse (France)

### 27. Heteroepitaxial growth of SrTiO<sub>3</sub> on Si(001) by molecular beam epitaxy

G. Delhaye, G. Saint-Girons, L. Largeau, G. Patriarche, C. Merckling, M. El Kazzi, M.Gendry, G. Hollinger, Y. Robach

Workshop "Silicon/oxide Hetero-Epitaxy: A New Road Towards A Si CMOS-Compatible Resonant Tunnel Diode Technology?", 11-12 september 2006, Como (Italy).

### 28. Epitaxial growth of γ-Al<sub>2</sub>O<sub>3</sub> and LaAlO<sub>3</sub> on silicon

C. Merckling, M. El-Kazzi, G. Delhaye, S. Gaillard, L. Becerra, L. Rapenne, B. Chenevier, O. Marty, L. Largeau, G. Patriarche, G. Grenet, M. Gendry, Y. Robach, G. Saint-Girons, G. Hollinger

Workshop "Silicon/oxide Hetero-Epitaxy: A New Road Towards A Si CMOS-Compatible Resonant Tunnel Diode Technology?", 11-12 september 2006, Como (Italy).

### 29. Resonant Tunneling Diode Al<sub>2</sub>O<sub>3</sub> / Si / Al<sub>2</sub>O<sub>3</sub>

L. Becerra, C. Merckling, Mario El-Kazzi, G. Saint-Girons, A. Poncet, L. Militaru, C. Plossu, P. Rojo Romeo, G. Hollinger

Workshop "Silicon/oxide Hetero-Epitaxy: A New Road Towards A Si CMOS-Compatible Resonant Tunnel Diode Technology?", 11-12 september 2006, Como (Italy).

### 30. Oxydes à l'interface entre micro et optoélectronique

L. Largeau, G. Patriarche, G. Saint-Girons, P. Regreny, Cl. Merckling, G. Hollinger Conference de la société française de microscopie, june 5-8 2007, Grenoble (France)

### 31. Projet d'Integration de nanofils III-V sur silicium

H. Dumont, M. Gendry, P. Rojo-Romeo, G. Saint-Girons, C. Bru-Chevallier Workshop du GDR nanofils, may 9-11 2007, Ecully (France)

## 32. Epitaxial growth of "high- $\kappa$ " oxides on silicon for advanced CMOS: LaAlO3, Gd2O3, $\gamma$ -Al2O3

C. Merckling, M. El-Kazzi, L. Becerra, G. Saint-Girons, G. Delhaye, G. Patriarche, L. Largeau, V. Favre-Nicolin, O. Marty, and G. Hollinger

International Workshop on functional oxides, march 16-19 (2008) – Autrans (France)

## 33. Mise en évidence par diffraction de photoélectrons de la déformation ferroélectrique de BaTiO<sub>3</sub> contraint sur SrTiO<sub>3</sub>(001)

M. El Kazzi, G. Delhaye, G. Saint-Girons, C.Merckling, G. Grenet et G. Hollinger International Workshop on functional oxides, march 16-19 (2008) – Autrans (France)

### 34. Epitaxie directe de SrTiO3 (sans recuit post-dépôt) sur silicium

G. Niu, B. Vilquin, G. Delhaye, G. Saint-Girons, Y. Robach, G. Hollinger International Workshop on functional oxides, march 16-19 (2008) – Autrans (France)

## 35. Caractérisation électrique d'oxydes à forte constante diélectrique épitaxiés sur Si(001) : évaluation pour applications MOSFET

L. Becerra, C. Merckling, M. El-Kazzi, N. Baboux, G. Saint-Girons, B. Vilquin, C. Plossu, G. Hollinger

International Workshop on functional oxides, march 16-19 (2008) – Autrans (France)

### 36. Etude de la croissance de boîtes quantiques d'InP sur SrTiO<sub>3</sub>/Si

J. Cheng, G. Saint-Girons, P. Regreny, G. Patriarche, L. Largeau, C. Priester, V. Favre-Nicolin, G. Grenet et G. Hollinger

International Workshop on functional oxides, march 16-19 (2008) – Autrans (France)

### 37. Molecular Beam Epitaxy of InP quantum dots on SrTiO<sub>3</sub>/Si(001) crystalline buffers

J. Cheng, G. Saint-Girons, P. Regreny, G. Grenet, Y. Robach, M. Gendry, G. Hollinger, G. Patriarche, Ludovic Largeau

JNMO 2008, June 3-6 2008 – Oléron (France)

### 38. Caractérisation d'interfaces oxyde/silicium par diffraction de photoélectrons

M. El Kazzi, C.Merckling, G. Delhaye, G. Saint-Girons, G. Grenet et G. Hollinger Journées Surfaces Interfaces, January 28-30 2008 – Grenoble (France)

### 39. Study of the epitaxy of InP quantum dots on SrTiO<sub>3</sub>/Si(001) crystalline buffers

J. Cheng, G. Saint-Girons, P. Regreny, G. Patriarche, L. Largeau, G. Grenet<sup>1</sup>, Y. Robach and G. Hollinger

Keio Workshop, February 27-29 2008 – Ecully (France)

### 40. Imagerie STEM-HAADF d'interfaces de semi-conducteurs III-V sur oxydes cristallins

L. Largeau, G. Patriarche, G. Saint-Girons, J. Cheng, P. Regreny, G. Hollinger

Conférence de la société française de Microscopie, 22-26 juin 2009, Paris (France)

### 41. Epitaxy and characterization of crystalline high-k oxide on silicon by MBE.

G. Niu, B. Vilquin, G. Saint-Girons, L. Becerra, G. Delhaye, Y. Robach, G. Grenet and G. Hollinger

ECL-Keio Workshop, Ecole Centrale de Lyon, February 2009.

#### 42. Intégration monolithique de matériaux III-V sur Si via un tampon d'oxyde high-k

J. Cheng, G. Saint-Girons, P. Regreny, G. patriarche, L. Largeau, P. Rojo-Romeo and G. Hollinger

12ème JNRDM, 17-19 mai 2009, Lyon (France)

## 43. Effect of the substrate on the nanowire crystalline quality: case of InP nanowires gorwn on Si, SrTiO3 and InP substrates.

H. Dumont, K. Naji, P. Regreny, G. Saint-Girons, G. Patriarche and M. Gendry.

Workshop du GDR "Nanofils et Nanotubes semiconducteurs", 30 juin au 3 juillet 2009, Autrans (France).

### 44. Epitaxie d'oxydes cristallins « high-k » sur silicium

G. Niu, B. Vilquin, G. Saint-Girons, C. Botella, G. Grenet, P. Regreny, M. Gendry, Y. Robach, G. Hollinger, N. Baboux, C. Plossu, B. Canut, B. Blein, S. Autier-Laurent, P. Lecouer, JL. Maurice

12ème JNRDM, 17-19 mai 2009, Lyon (France)

## 45. MBE growth of III-V nanostructures (quantum dots and nanowires) on silicon for photonics

M. Gendry, H. Dumont, K. Naji, Y. Robach, G. Saint-Girons, P. Rojo-Romeo, P. Regreny, R. Ray, C. Bru-Chevallier and G. Patriarche

ECL-Keio Workshop, Ecole Centrale de Lyon, February 2009.

## 46. Structural and chemical studies of epitaxial $\gamma$ -Al<sub>2</sub>O<sub>3</sub> thin films grown on Si(001) and Si(111) using XPD and synchrotron radiation photoemission

M. El-Kazzi, C. Merckling, G. Saint-Girons, G. Grenet, M. Silly, F. Sirotti and G. Hollinger 2010 SOLEIL user meeting, january 20-21, 2010, Ecole Polytechnique Palaiseau (France)

### 47. Semiconductor/oxide interfaces for monolithic integration of III-V and Ge on Si

B. Gobaut, G. Saint-Girons, J. Penuelas, G. Grenet, J. Cheng, A. Chettaoui, L. Largeau, G. Patriarche, M. El-Kazzi

International workshop and winter school: photoemission, February 21-27, 2010, Dijon (France).

### 48. Structural and optical properties of InP NWs grown on Si(001) by VLS-SSMBE

M. Gendry, K. Naji, H. Dumont, G. Saint-Girons, J. Penuelas, N. Chauvin, C. Bru-Chevallier and G. Patriarche

5th workshop on nanowire growth, november 4-5, 2010, Roma (Italy).

## 49. Epitaxie directe d'hétérostructures III-V sur silicium en utilisant des templates de SrTiO<sub>3</sub>/Si.

A. Chettaoui, B. Gobaut, J. Penuelas, J. Cheng, G. Niu, L. Largeau, P. Regreny, G. Saint-Girons 13èmes journées Nano, Micro et Optoélectronique, septembre 28 to october 1<sup>st</sup>, 2010, Les Issambres (France).

### 50. Intégration monolithique de semiconducteurs III-V sur Si.

B. Gobaut, J. Penuelas, A. Chettaoui, J. Cheng, G. Grenet, G. Saint-Girons, L. Largeau and M. El-Kazzi

13èmes journées Nano, Micro et Optoélectronique, septembre 28 to october 1<sup>st</sup>, 2010, Les Issambres (France).

### 51. Forme, orientation et structure cristalline des nanofils d'InP crus sur Silicium par VLS-EJM

K. Naji, H. Dumont, G. Saint-Girons, N. Chauvin, C. Bru-Chevallier, M. Gendry and G. Patriarche

13èmes journées Nano, Micro et Optoélectronique, septembre 28 to october 1<sup>st</sup>, 2010, Les Issambres (France).

# 52. Dépôt par Jet Moléculaire de LaAlO3 sur silicium pour les nœuds technologiques CMOS 22 nm : vers un contrôle parfait de l'hétéro-interface oxyde/silicium S. Pelloquin

JNRDM 2010, 7-9 juin 2010, Montpellier (France).

### 53. Etude par photoémission de l'interface Ge/SrTiO3

D. Ferrah, B. Gobaut, J. Penuelas, G. Grenet, G. Saint-Girons, M. El-Kazzi, M. Silly, F. Sirotti, J. Avila, I. Razado Colambo et M.C. Asensio

25<sup>ème</sup> journées surfaces et interfaces, 26-28 janvier 2011, Poitiers (France)

## 54. Size, shape and epitaxy of Ge nanodots on STO studied by grazing incidence X-ray diffraction

B. Gobaut, J. Penuelas, N. Blanc, V. Favre-Nicolin, G. Renaud and G. Saint-Girons 9ème colloque Rayons X et Matière, 28/11-01/12 2011, Tours (France).

### 55. Présentation à mi-Parcours du projet COMPHETI

G. Saint-Girons

J3N 2011, november 7-9 (2011), Strasbourg (France)

### 56. Ge sur SrTiO<sub>3</sub>: adhésion et mouillage

B. Gobaut, J. Penuelas, G. Grenet and G. Saint-Girons

Workshop "adhésion-collage-mouillage" du GDR MECANO, 6-7 octobre 2011, Ecully (France).

### 57. Epitaxy of piezoelectric Pb(Zr,Ti)O<sub>3</sub> (PZT) film on silicon for energy harvesting

R. Bachelet, A. Borowiak, B. Gautier, Q. Liu, L. Louahadj, C. Malhaire, O. Marconot, G. Niu, J. Penuelas, J. Pezard, M. Piquemal, Y. Robach, P. Rojo-Romeo, G. Saint-Girons, B. Vilquin Colloque 2012 de l'UMI LN2, 15 au 18 juillet 2012, Sherbrooke (Canada)

### 58. Etude par photoémission de l'interface Ge/SrTiO3

B. Gobaut, J. Penuelas, D. Ferrah, G. Grenet, G. Saint-Girons, M. El-kazzi, M. Silly, F. Sirotti, J. Avila, I. Razado Colambo, M.-C. Asensio

Journées Surfaces et interfaces 2012, 25-27 janvier 2012, synchrotron SOLEIL, L'Orme des Merisiers (France)

## 59. Epitaxial perovskite oxides on silicon for thermal energy harvesting in monolithic nanoelectronic devices

R. Bachelet, L. Louahadj, G. Niu, C. Dubourdieu, J. Penuelas, B. Vilquin, G. Saint-Girons Réunion du GDR Thermoélectricité, 05-06 décembre 2012, Lyon

### 60. Présentation du projet COMPHETI

G. Saint-Girons

J3N 2012, nov.7-9 2012, Bordeaux (France)

## 61. Croissance de SrTiO<sub>3</sub>/Si : réactivité de l'interface et impact sur les propriétés structurales de la couche épitaxiée

L. Louahadi, G. Niu, R. Bachelet, C. Chaix, G.Saint-Girons

Conference JMC 2012, august 27-31 (2012), Montpellier (France)

## 62. Les développements de l'épitaxie par jets moléculaires pour la croissance d'oxydes pérovskites sur silicium

P. Regreny, C. Botella, J.B. Goure, L. Louahadj, R. Bachelet, C. Chaix, G. Saint-Girons Colloque annuel du GDR pulse, 3-5 juillet 2013, Aix en Provence (France)

### 63. Monolithic integration of functional oxides on GaAs

D. Le Bourdais, G. Agnus, P. Regreny, P. Lecoeur, L. Largeau, V. Pillard, P. Gogol, R. Bachelet, L. Louahadj, C. Dubourdieu and G. Saint-Girons

Journées nationales des technologies émergentes, 21-23 mai 2013, Evian les Bains (France).

## 64. Oxide films and nanostructures on silicon for thermal energy harvesting in microelectronic devices

R. Moalla, A. Carretero-Genevrier, L. Mazet, L. Louahadj, J. Penuelas, B. Vilquin, C. Dubourdieu, G. Saint-Girons, R. Bachelet

Réunion du GDR Thermoélectricité, 9-10 décembre 2013, Nancy (France)

## 65. Croissance de Pt sur la couche mince d'oxyde Gd2O3 (111) épitaxie sur Si(111) : Etude par photoémission

D. Ferrah, G. Grenet, Y. Robach, Q. Liu, L. Louahadj, J. Penuelas, G. Niu, G. Saint-Girons, B. Vilquin

Journées surfaces et interfaces, 20 janvier – 1 février 2013, Orléans (France)

### 66. Resistive switching of HfO<sub>2</sub>-based metal-insulator-metal devices

M. Minvielle, R. Bachelet, G. Saint-Girons, G. Ghibaudo, F. Alibart, C. Dubourdieu CRIEC 2014, june 1-5 2014, Ecole Centrale de Lyon, Ecully (France)

# 67. BaTiO<sub>3</sub> grown on Si (001) by Molecular Beam Epitaxy for low power field-effect devices L. Mazet, R. Bachelet, L. Louahadj, D. Albertini, B. Gautier, G. Saint-Girons, C. Dubourdieu 28èmes Journées Surfaces et Interfaces, 29-31 Janvier 2014, Ecully, (France)

### 68. Ti-based interface engineering for heteroepitaxial growth of SrTiO3 on GaAs

B. Meunier, L. Louahadj, G. Grenet, C. Botella, P. Regreny, R. Bachelet, J. Penuelas, G. Renaud, G. Saint-Girons

28èmes Journées Surfaces et Interfaces, 29-31 Janvier 2014, Ecully, (France)

### 70. BaTiO<sub>3</sub> grown on Si and SOI by molecular beam epitaxy for nanoelectronics

L. Mazet, R. Bachelet, L. Louahadj, D. Albertini, B. Gautier, G. Saint-Girons, C. Dubourdieu 13èmes Journées de Caractérisation Microondes et Matériaux, 24-26 Mars 2014, Nantes, (France)

### 71. Systèmes épitaxiés combinant oxydes et semiconducteurs

G. Saint-Girons, J. Penuelas, A. Danescu, B. Gobaut, A. Chettatoui, G. Grenet, G. Renaud, V. Favre Nicolin, N. Blanc, T. Zhou, M. El-Kazzi, M. Silly and F. Sirotti

Atelier nucléation du GDR PULSE, 7-8 avril 2014, CRHEA, Valbonne, (France).

## 72. Epitaxial Growth of Ferroelectric Pb(Zr,Ti)O<sub>3</sub> thin Layers on SrTiO<sub>3</sub>-templated GaAs/InGaAs quantum well structure for opto-mechanical application

B. Meunier, L. Louahadj, D. Le Bourdais, L. Largeau, N. Chauvin, G. Agnus, P. Lecoeur, V. Pillard, R. Bachelet, P. Regreny, C. Botella, G. Grenet and G. Saint-Girons

Workshop "Les oxydes pour l'optique et la photonique", 8-9 décembre 2014, Meudon, (France).

### 73. Epitaxial growth by molecular beam epitaxy of ferroelectric BaTiO<sub>3</sub> on silicon

L. Mazet, R. Bachelet, G. Saint-Girons, S. Yang, S. Kalinin, M. Hÿtch, S. Schamm-Chardon, C. Dubourdieu

Workshop "Les oxydes pour l'optique et la photonique", 8-9 décembre 2014, Meudon, (France).

### 74. Electro-optic modulation using hybrid silicon-ferroelectric oxide slot waveguide

S. Cueff, X. Hu, R. Orobtchouk, P. Rojo Romeo, R. Bachelet, B. Vilquin, C. Dubourdieu, P. Regreny, C. Botella, G. Grenet, G. Saint-Girons, P. Castera, N. Sanchez, T. Angelova, L. Bellieres, A. Griol, A. M. Gutierrez, P. Sanchis

Workshop "Les oxydes pour l'optique et la photonique", 8-9 décembre 2014, Meudon, (France).

## 75. Capping and decapping GaAs nanowires with As for preventing oxidation and for epitaxial shell growth

X. Guan, J. Becdelievre, N. Benali, C. Botella, G. Grenet, P. Regreny, M. Gendry, G. Saint-Girons, J. Penuelas

8èmes Entretiens pour la Recherche Beihang-GEC, 21-22 mai 2015, Ecole Centrale Marseille, (France)

### 76. Epitaxial La-doped SrTiO<sub>3</sub>-based films of enhanced ZT

M. Apreutesei, P. Regreny, G. Saint-Girons, C. Botella, G. Grenet, A. Carretero-Genevrier, J. Gazquez, P. O. Chapuis, R. Debord, S. Pailhès, R. Bachelet Réunion du GDR thermoélectricité, 13-14 octobre 2015, CRYSMAT (Caen)

## 77. Epitaxial Growth of Ferroelectric Pb(Zr,Ti)O<sub>3</sub> thin Layers on SrTiO3-templated GaAs/InGaAs quantum well structure for opto-mechanical application

B. Meunier, L. Louahadj, D. Le Bourdais, L. Largeau, N. Chauvin, G. Agnus, P. Lecoeur, V. Pillard, R. Bachelet, P. Regreny, C. Botella, G. Grenet and G. Saint-Girons ISOE 2015 summer school, 12-24 octobre 2015, Cargese, (France)

## 78. SrTiO<sub>3</sub> thin layers on Si: epitaxy and use as templates for thermal energy management and photonic integrated devices

S. Cueff, M. Apreutesei, R. Moalla, B. Meunier, X. Hu, G. Grenet, J. Penuelas, P. Regreny, C. Botella, A. Carretero, R. Orobtchouk, P. Rojo-Romeo, B. Vilquin, N. Baboux, M. Silly, F. Sirotti, J. Gazquez, P.O. Chapuis, R. Debord, S. Pailhès, R. Bachelet and G. Saint-Girons JNTE 2015, 18-20 novembre 2015, Lyon, (France)

## 79. SrTiO<sub>3</sub>/GaAs epitaxial templates: role of Ti at the interface, and application to the fabrication of novel opto-mechanical devices

B. Meunier, R. Bachelet, G. Grenet, C. Botella, P. Regreny, L. Largeau, J. Penuelas and G. Saint-Girons

JSI 2015, 28-30 janvier 2015, Toulouse, (France)

## 80. Chemical Solution Deposition of Functional Oxide thin Films and Nanostructures on Silicon

J. M. Vila-Fungueiriño, R. Bachelet, G. Saint-Girons, M. Gendry, M. Gich, J. Gazquez, E. Ferain, F. Rivadulla, J. Rodriguez-Carvajal, N. Mestres and A. Carretero-Genevrier Workshop Nano-nano 2015, 15-16 juin 2015, Lyon, (France)

### 81. Nanofils coeur GaAs coquille P(VDF-TrFe)

J. Becdelièvre, G. Xuan, N.P. Blanchard, P. Vincent, P. Regreny, P. Rojo-Romeo, B. Vilquin, M. Gendry, A. Danescu, B. Gautier, D. Albertini, G. Saint-Girons, J. Penuelas Workshop Nano-nano 2015, 15-16 juin 2015, Lyon, (France)

## 82. Emetteurs quantiques et matériaux commutables pour le contrôle dynamique de composants nanophotoniques

S. Cueff, R. Orobtchouk, P. Rojo-Romeo, G. Saint-Girons, X. Letartre Workshop Nano-nano 2015, 15-16 juin 2015, Lyon, (France)

### 83. Oxide nanostructures for thermoelectricity

M. Apreutesei, R. Moalla, G. Grenet, G. Saint-Girons, S. Pailhès, A. Carretero-Genevrier, R. Bachelet

Workshop Nano-nano 2015, 15-16 juin 2015, Lyon, (France)

### 84. GaAs nanowires with oxidation-proof As cap for the growth of epitaxial shell

X. Guan, J. Becdelievre, A. Benali, C. Botella, G. Grenet, H. Dumont, P. Regreny, G. Saint-Girons, M. Gendry, J. Penuelas

Workshop Nano-nano 2015, 15-16 juin 2015, Lyon, (France)

### 85. Core-shell nanowires for piezotronics

J. Becdelievre, X. Guan, N.P. Blanchard, P. Vincent, P. Regreny, P. Rojo-Romeo, B. Vilquin, M. Gendry, A. Danescu, B. Gautier, D. Albertini, G. Saint-Girons, J. Penuelas PULSE summer school 2015, 14-18 septembre 2015, Porquerolles, (France)

## 86. Integration of BaTiO<sub>3</sub> epitaxial ferroelectric on semiconductors: growth parameters and tetragonality at the nanoscale

S. Schamm-Chardon, C. Magen, L. Mazet, R. Cours, R. Bachelet, G. Saint-Girons, M. Hÿtch, and C. Dubourdieu

Workshop OXYFUN/MECANO "strain in oxydes", 16-17 avril 2015, Leuven (Belgique)

### 87. Mechanical characterization of core (GaAs) - shell nanowires

J. Becdelievre, X. Guan, A. Viera Silva, N.P Blanchard, P. Vincent, A. Danescu, P. Regreny,

P. Rojo-Romeo, B. Vilquin, M. Gendry, G. Grenet, B. Gautier, D. Albertini, G. Saint-Girons, J. Penuelas

Réunion du GDR Mecano, 1-2 octobre 2015, Toulouse, (France)

## 88. SrTiO<sub>3</sub>/Si templates: growth mechanism and application to on-chip thermal energy management and integrated photonics

R. Bachelet, B. Meunier, R. Moalla, S. Cueff, M. Apreutesei, L. Louahadj, G. Grenet, J. Penuelas, P. Regreny, C. Botella, R. Orobtchouk, P. Rojo-Romeo, B. Vilquin, N. Baboux, A. Carretero-Genevrier, M. Silly, F. Sirotti, J. Gazquez, P.O. Chapuis, R. Debord, S. Pailhès, B. Canut, G. Saint-Girons

JNMO 2016, 30 mai  $-1^{er}$  juin 2016, Les Issambres, (France).

## 89. GaAs nanowires with oxidation-proof arsenic capping/decapping method for the growth of an epitaxial Shell

X. Guan, J. Becdelievre, A. Benali, C. Botella, G. Grenet, H. Dumont, N. Chauvin, P. Regreny, G. Saint-Girons, M. Gendry, J. Penuelas Journées Surfaces-Interfaces 2016, 27-29 janvier 2016, Marseille (France)

## 90. SrTiO<sub>3</sub> thin layers on Si: epitaxy and use as templates for thermal energy management and photonic integrated devices

R. Bachelet, B. Meunier, R. Moalla, S. Cueff, M. Apreutesei, X. Hu, G. Grenet, J. Penuelas, P. Regreny, C. Botella, A. Carretero-Genevrier, R. Orobtchouk, P. Rojo-Romeo, B. Vilquin, N. Baboux, M. Silly, F. Sirotti, J. Gazquez, P.O. Chapuis, R. Debord, S. Pailhès and G. Saint-Girons

Colloque annuel du GDR PULSE, 18-22 juillet 2016, Marseille (France).

### 91. Thermoelectric properties of (La,Sr)TiO<sub>3</sub> epitaxial films deposited by MBE

M. Apreutesei, P. Regreny, G. Saint-Girons, C. Botella, G. Grenet, A. Carretero-Genevrier, J. Gazquez, P. O. Chapuis, R. Debord, G. Bouzerar, S. Pailhès, R. Bachelet Réunion du GIS Thermoélectricité, 24-25 novembre 2016, Lyon (France)

### 92. Perovskite oxide engineering using Molecular Beam Epitaxy

M. Bouras, R. Bachelet, G. Saint-Girons ISOE 2017 summer school, 11-21 avril 2017, Cargese (France)

### 93. GaAs Core / SrTiO3 Shell Nanowires Grown by Molecular Beam Epitaxy

X. Guan, J. Becdelievre, G. Saint-Girons, R. Bachelet, P. Regreny, C. Botella, G. Grenet, N. P. Blanchard, M. Gendry, J. Penuelas J2N 2017, 13-15 novembre 2017, Grenoble (France)

### 94. Perovskite oxides grown by MBE for integrated thermoelectricity

M. Apreutesei, R. Debord, M. Bouras, D. Han, P. Regreny, C. Botella, G. Grenet, Q. d'Acremont, S. Dilhaire, P.O. Chapuis, S. Pailhès, G. Saint-Girons, R. Bachelet Journées Nationales de la Thermoéletricité, 6 au 7 décembre 2017, Montpellier (France)

## 95. Combining physical and chemical processes to add new functionalities in epitaxial oxides on silicon

J. M. Vila-Fungueriño, A. Gomez, J. Gazquez, C. Magen, G. Saint-Girons, R. Bachelet, A. Carretero-Genevrier

Congrès AFC 2018, 10-13 juillet 2018, Lyon (France)

### 96. Phases Ruddlesden-Popper $Sr_{n+1}Ti_nO_{3n+1}$ hyperboliques épitaxiées par MBE

M. Elhachmi Bouras, R. Bachelet, D. Han, S. Cueff, G. Saint-Girons Congrès AFC 2018, 10-13 juillet 2018, Lyon (France)

## 97. Indefinite permittivity in $Sr_{n+1}Ti_nO_{3n+1}$ Ruddlesden-Popper thin layer grown by molecular beam epitaxy

M. Bouras, S. Cueff, L. Pedesseau, R. Bachelet, D. Han, L. Largeau, J. Even and G. Saint-Girons

Journées Nano-Micro-Optoélectronique, 13-15 juin 2018, Agay (France)

## 98. Engineering the properties of functional oxides and integrating them on Si and GaAs thanks to molecular beam epitaxy

M. Bouras, S. Cueff, L. Pedesseau, J. Even; R. Bachelet, D. Han, J. Penuelas, G. Grenet, P. Regreny, N. Chauvin, L. Largeau, G. Saint-Girons

Journées nationales du GDR OXYFUN, 21-23 mars 2018, Piriac sur mer (France)

### 99. Oxides grown by MBE for integrated thermoelectricity

D. Han, M. Bouras, M. Apreutesei, R. Debord, R. Moalla, P. Regreny, C. Botella, G. Grenet, J. Gazquez, M. Bugnet, S. Dilhaire, P.O. Chapuis, S. Pailhès, G. Saint-Girons, R. Bachelet 3eme rencontre du LRA en Nanothermique Lyonnais, 23 mars 2018, Lyon (France)

### 100. Hybrid core - shell nanowires grown by molecular beam epitaxy

J. Penuelas, T. Dursap, L. Fouquat, M. Vettori, X. Guan, C. Botella, P. Regreny, N. Chauvin, R. Bachelet, G. Saint-Girons, A. Danescu, G. Grenet, M. Bugnet, G. Patriarche, M. Gendry Congrès CNano 2018, 11-13- décembre 2018, Toulon (France)

## 101. Système d'analyse RHEED adapté au contrôle de la croissance de couches minces d'oxydes fonctionnels et de nanofils III-V

C. Botella, M. Bouras, T. Dursap, D. Han, M. Vettori, R. Bachelet, J. Penuelas, M. Gendry et G. Saint-Girons

Atelier du GDR PULSE, october 01-03, 2018, Toulouse, France.

### 102. Hétérostructures à base de nanofils III-V

J. Penuelas, X. Guan, J. Becdelièvre, L. Fouquat, P. Regreny, M. Gendry, G. Saint-Girons, R. bachelet, A; Danescu, C. Botella, G. Grenet Journées surfaces et interfaces, 01 janvier 2018, Strasbourg (France)

### 103. Perovskite-Oxide Based Hyperbolic Metamaterials

M. Bouras, D. Han, S. Cueff, R. Bachelet and G. Saint-Girons

Journées « couches minces d'oxydes fonctionnels et applications en électronique et photonique » du GDR OXYFUN, 1-2 octobre 2019, Caen (France)

### 104. (La,Sr)TiO<sub>3</sub>/SrTiO<sub>3</sub> superlattices as hyperbolic metamaterials

M. Bouras, D. Han, S. Cueff, R. Bachelet and G. Saint-Girons

Conference plénière du GDR PULSE, 1-4 juillet 2019, Clermont-Ferrand (France)

## 105. Localized oxide MBE growth on Si by selective etching lift-off for on-chip thermoelectricity

R. Moalla, D. Han, G. Saint-Girons, J.-L. Leclercq, and R. Bachelet JNTE 2019, 25-27 novembre 2019, Grenoble (France)

### 106. Functional oxide based epitaxial metamaterials in the NIR-MIR

G. Saint-Girons, S. Cueff, R. Bachelet, M. Bouras Rencontres du Moyen Infrarouge, 22 october 2019, Rennes (France)

### 107. P-type thermoelectric LaCrO<sub>3</sub>-based epitaxial films grown by MBE

D. Han, M. d'Esperonnat, M. Bouras, R. Moalla, C. Botella, A. Benamrouche, G. Grenet, B. Canut, R. Debord, V. Giordano, S. Pailhès, G. Saint-Girons and R. Bachelet JNTE 2020, 18-19 november 2020, Lille (France) *cancelled* 

### 108. Solid solutions and superlattices of perovskite oxides for enhanced thermoelectricity

M. d'Esperonnat, D. Han, R. Moalla, M. Razaghi, C. Botella, B. Canut, N. Baboux, G. Saint-Girons, R. Bachelet

Journées Nationales du GDR OXYFUN, 2020 Guétary (France) cancelled

## 109. Superlattices and Ruddlesden-Popper phases to engineer the optical properties of perovskite oxides

M. Razaghi, M. d'Esperonnat, M. Bouras, D. Han, S. Cueff, R. Bachelet and G. Saint-Girons Journées Nationales du GDR OXYFUN, 2020 Guétary (France) *cancelled* 

## 110. Tuning transport properties by epitaxial strain in p-type Sr-doped LaCrO3 transparent thin films grown by MBE

D. Han, R. Moalla, I. Fina, V.M. Giordano, M. d'Esperonnat, C. Botella, G. Grenet, R. Debord, S. Pailhès, G. Saint-Girons, and R. Bachelet

Workshop virtuel sur l'épitaxie des oxydes (EPIDOX), November 17-19<sup>th</sup>, 2021

## 111. Sensitive RHEED signature of Ti-excess enabling enhanced cationic composition control during the molecular beam epitaxy of SrTiO3 based solid solutions

M. Razaghi, M. d'Esperonnat, C. Botella, S. Cueff, R. Bachelet and G. Saint-Girons Workshop virtuel sur l'épitaxie des oxydes (EPIDOX), November 17-19<sup>th</sup>, 2021

## 112. Epitaxie et orientations préférentielles de nanoparticules de FeRh préformées par vaporisation laser et déposées sur BaTiO3 ou SrTiO3

F. Tournus, G. Herrera-Huerta, D. Le Roy, V. Dupuis, A. Reyes, I. Cañero-Infante, G. Saint-Girons, R. Bachelet, A. Resta, L. Martinelli, X. Weng, G. Renaud Conférence de l'AFC, June 29 – July 2, 2021, Grenoble (France)

## 113. Epitaxy and interfacial coupling of FeRh nanoparticles deposited on BaTiO3 or SrTiO3 surfaces

F. Tournus, G. Herrera-Huerta, D. Le Roy, V. Dupuis, C. Raton, A. Reyes, I. Cañero-Infante, P. Rojo-Romeo, B. Vilquin, G. Saint-Girons, R. Bachelet, A. Resta, P. Ohresser, E. Otero, L. Martinelli, X. Weng, G. Renaud

JMC 2021, august 24-27 2021, Rennes (France)

## 114. Tuning thermoelectric properties by epitaxial strain in p-type Sr-doped LaCrO<sub>3</sub> thin films

D. Han, R. Moalla, I. Fina, V. Giordano, M. d'Esperonnat, C. Botella, G. Grenet, R. Debord, S. Pailhes, G. Saint-Girons and R. Bachelet

1st Japan-France virtual workshop on thermoelectrics, September 27-30 2021, vitual

## 115. Sb<sub>2</sub>S<sub>3</sub> thin film for tunable nanophotonic devices: phase switching mechanisms and thin film characterization

C. Laprais, L. Berguiga, G. Saint Girons, N. Baboux, S. Cueff 1ères Journées Scientifiques du GDR CHALCO, june 20-21 2022, Dijon (France)

### 116. SrTi<sub>1-x</sub>Al<sub>x</sub>O<sub>3</sub> thin films epitaxially-grown by MBE for thermoelectric applications

M. d'Esperonnat, C. Adessi, C. Botella, G. Saint-Girons, R. Bachelet Journées Nationales du GDR OXYFUN, April 1-8, 2022 Guéthary, (France)

### 117. Pyroelectric and thermoelectric epitaxial oxide layers for thermal energy harvesting

R. Moalla, D. Han, M. d'Esperonnat, C. Botella, B. Vilquin, N. Baboux, G. Saint-Girons, R. Bachelet

Journées Nationales du GDR OXYFUN, April 1-8, 2022 Guéthary, (France)

### 118. Structural disorder in SrTiO3 based Ruddlesden-Popper phases

C. Furgeaud, A. Danescu, R. Bachelet, L. Largeau, M. Bouras and G. Saint-Girons CNANO conference 2023, March 15-17, 2023, Poitiers, (France)

### 119. Structural disorder in SrTiO3 based Ruddlesden-Popper phases

C. Furgeaud, A. Danescu, R. Bachelet, L. Largeau, M. Bouras and G. Saint-Girons Conférence 2023 du GDR MATEPI, 3-6 juillet 2023, Paris (France)

## 120. La diffraction des photoélectrons X (XPD) comme sonde locale dans des hétérostructures épitaxiées

C. Botella, R. Bachelet, J Penuelas, I. Dudko, D. Han, R. Moalla, G. Saint-Girons, A. Lamirand et G. Grenet

JNSPE 2023, 31 mai-2 juin 2023, Sophia-Antipolis (France)

## 121. Optically switched Sb2S3 low loss phase change material for reconfigurable nanophotonic

C. Laprais, L. Berguiga, C. Zrounba, J. Bouvier, N. Baboux, G. Saint-Girons, S. Cueff 2èmes journées thématiques du GDR Chalco, 6-7 juin 2023, Bordeaux (France)

### 122. Advanced optical flux monitoring to control thin layer deposition processes

R. Rousseau, C. Botella, J. Morville, L. Berguiga, M. Bounab, C. Furgeaud, R. Bachelet and G. Saint-Girons

Workshop OSEPI 2024, 13-17 mai 2024, Frejus (France)

## 123. Pioneer operando curvature stress measurement during BaTiO3 thin film epitaxy by RF magnetron sputtering

C. Furgeaud, R. Rousseau, M. Bounab, P. Regreny, C. Botella, A. Danescu, R. Bachelet, G. Saint-Girons

Workshop OSEPI 2024, 13-17 mai 2024, Frejus (France)

## 124. Determination of the anisotropic dielectric function of epitaxial SrO(SrTiO3)n Ruddlesden-Popper structures (n=1,...5)

M. Bounab, C. Furgeaud, S. Cueff, R. Bachelet, M. Bouras, G. Saint-Girons Workshop OSEPI 2024, 13-17 mai 2024, Frejus (France)

### 125. Towards smart growth of functional materials with on-demand properties?

C. Furgeaud, M. Bounab, C. Botella, P. Regreny, R. Rousseau, G. Saint-Girons, R. Bachelet Journées plénières du GDR IAMAT, 2-5 juillet 2024, Toulouse (France)

#### 126. Advanced oxide MBE @ INL

R. Bachelet, C. Furgeaud, P. Regreny, R. Rousseau, M. Bounab, T. Zhu, C. Botella, J.B. Goure and G. Saint-Girons

Journées scientifiques du PEPR Electronique, 18-21 mars 2025, Paris (France)

### 127. Strong optical anisotropy in epitaxial SrO(SrTiO<sub>3</sub>)<sub>n</sub> Ruddlesden-Popper thin layers

M. Bounab, C. Furgeaud, S. Cueff, L. Berguiga, R. Bachelet, M. Bouras, L. Largeau, G. Saint-Girons

ISOE summer school, 8-18 juillet 2025, Cargese (France)

### 128. LaCoO<sub>3</sub> epitaxial thin films for advanced thermoelectric applications

T. Zhu, A. D. Lamirand, C. Furgeaud, C. Botella, A. Benamrouche, B. Fornacciari, B. Canut, P. Regreny, G. Saint-Girons, R. Bachelet

ISOE summer school, 8-18 juillet 2025, Cargese (France)

## 129. Molecular beam epitaxy of BaTiO<sub>3</sub> assisted by broadband cavity-enhanced optical flux monitoring

M. Bounab, R. Rousseau, R. Bachelet, C. Botella, J. Morville, A. Benamrouche, C. Furgeaud, G. Saint-Girons

MATEPI summer school, 22-27 juin 2025, Porquerolles (France)

### 130. Towards smart growth of functional materials with on-demand properties?

C. Furgeaud, M. Bounab, T. Zhu, C. Botella, P. Regreny, R. Rousseau, G. Saint-Girons, R. Bachelet

workshop "Machine Learning methods for Chemistry and Physics", 2-5 juin 2025, Lyon (France)